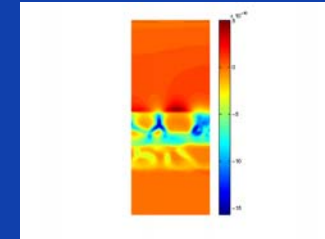
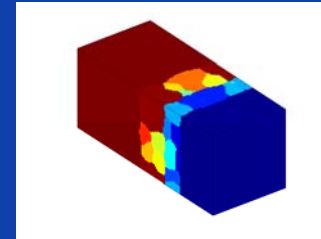
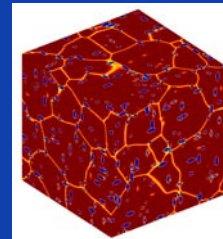


New directions in phase-field modeling of microstructure evolution in polycrystalline and multi-component alloys

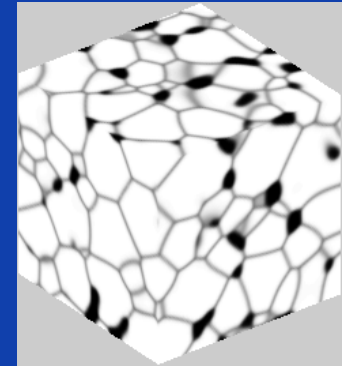
Nele Moelans

K.U. Leuven, Belgium

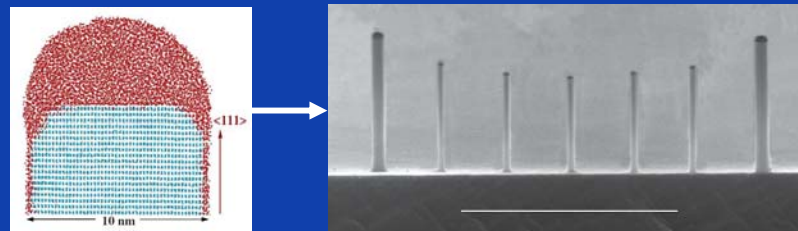
*School on Computational Modeling of
Materials, Antwerp, Dec 2-3, 2010*



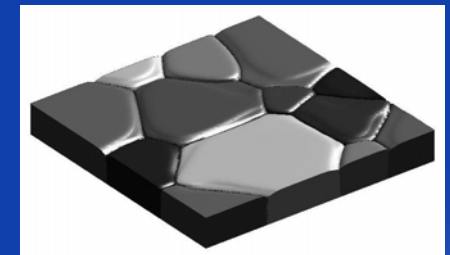
- **Modeling of microstructure evolution**
 - Meso- & micro scale (nm - mm)
 - Based on thermodynamic principles
- **Growing field since 20 years; current topics**
 - Quantitative aspects
 - Realistic, complex, multi component systems
- **Wide field of applications**
 - Solidification, phase transitions, diffusion, grain growth, deformation, crack formation, ferro-electric/magnetic domains, ...



Bulk grain structures

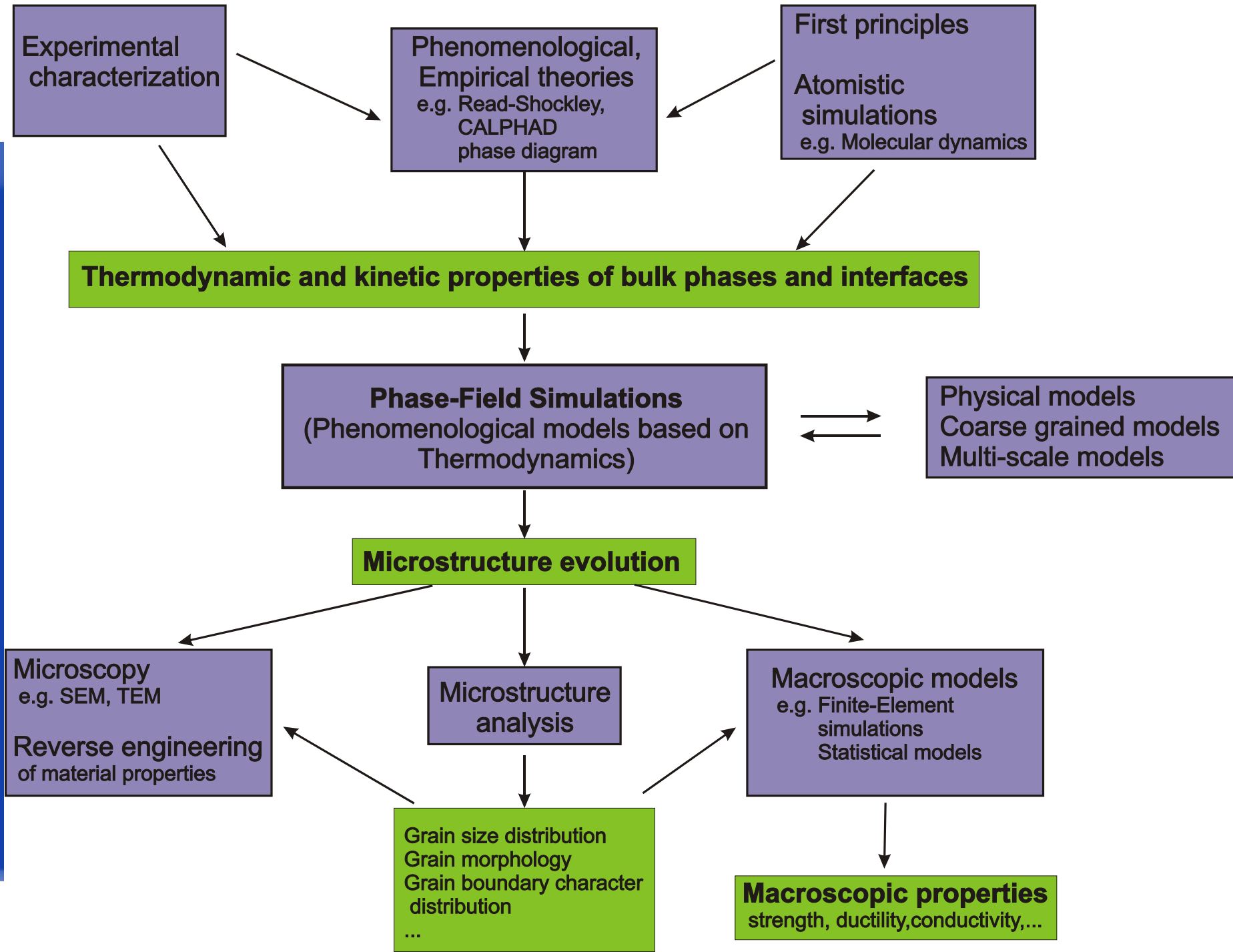


Synergetic growth of nanowires



Thin films

- **Properties bulk and interfaces are reproduced accurately in the simulations**
 - Effect model description and parameters
 - Numerical issues
- **=> Insights in the evolution of complex morphologies and grain assemblies**
 - Effect of individual bulk and interface properties
- **Predictive ?**
 - **Depends on availability and accuracy of input data**
 - Requires composition and orientation dependence



- **Different kinds of input data**
 - **Bulk phase stabilities, bulk phase diagram information**
 - CALPHAD
 - **Interfacial energy and mobility**
 - **Elastic properties, crystal structure, lattice parameters**
 - **Diffusion mobilities/coefficients**
 - DICTRA mobilities
- **Orientation and composition dependence**
 - **Anisotropy, segregation, solute drag**
 - **Very important for microstructure evolution, but difficult to measure/calculate**

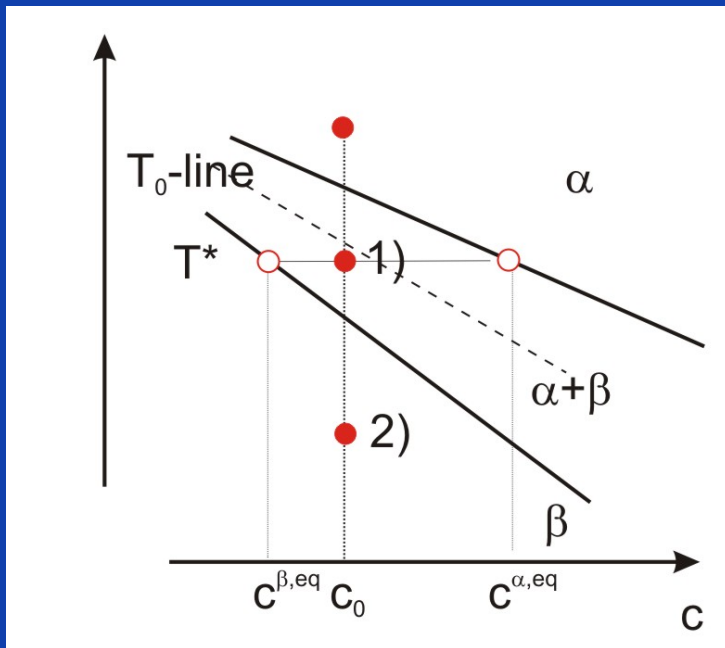
- **CALPHAD (CALculation of PHAse Diagrams) – method**
- **Quantitative phase-field model for multi-phase systems**
- **Coupling phase-field with thermodynamic databases, example for Ag-Cu-Sn**
- **Application examples**
 - **Diffusion controlled growth in Cu/Cu-Sn solder joints**

CALPHAD (CALculation of PHAse Diagrams) ***– method***

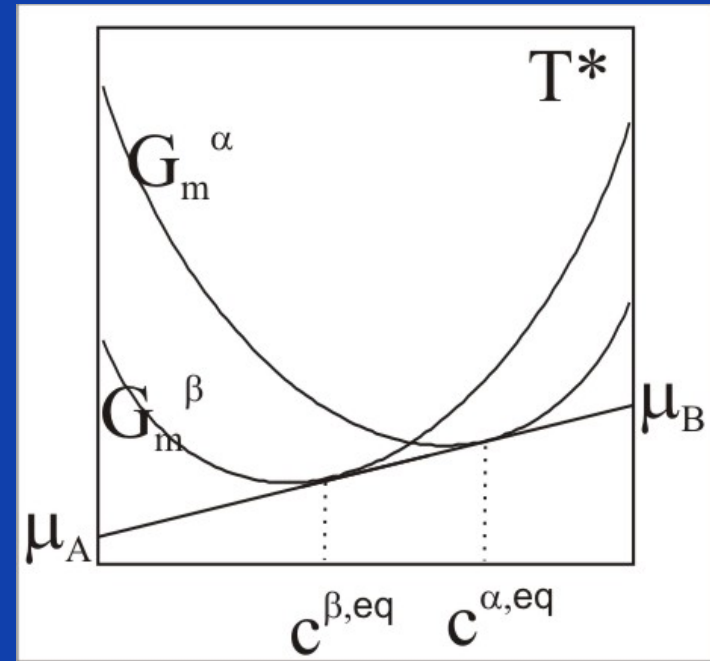
- *Computational thermodynamics: The Calphad Method, H.L. Lukas, S.G. Fries and B. Sundman, Cambridge 2007, ISBN 978-0-521-86811-2*
- *Thermo-Calc : www.thermocalc.se*
- *Calphad : www.calphad.org*

- Phase diagrams and thermodynamic Gibbs energies are combined

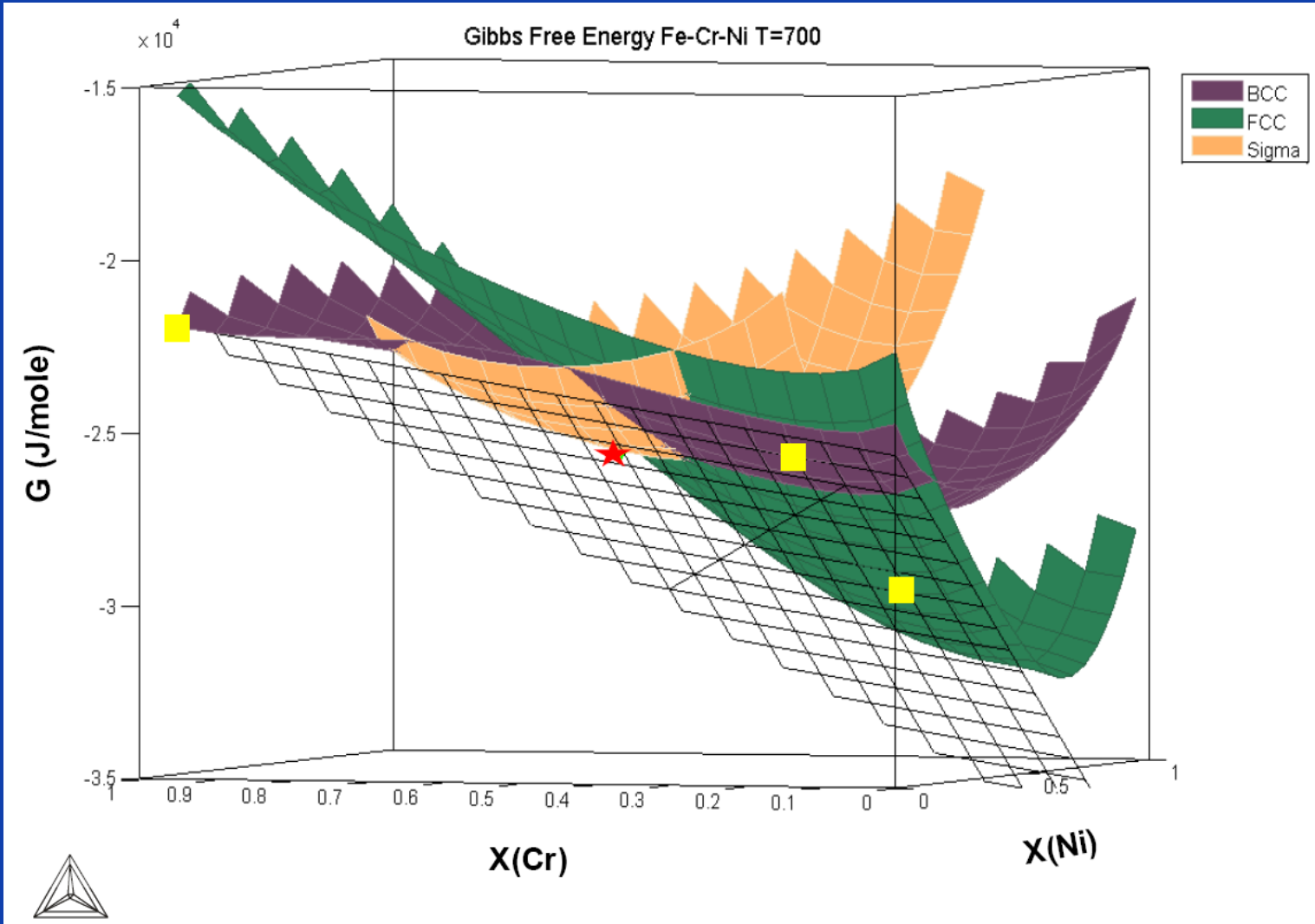
Phase diagram



Free energies

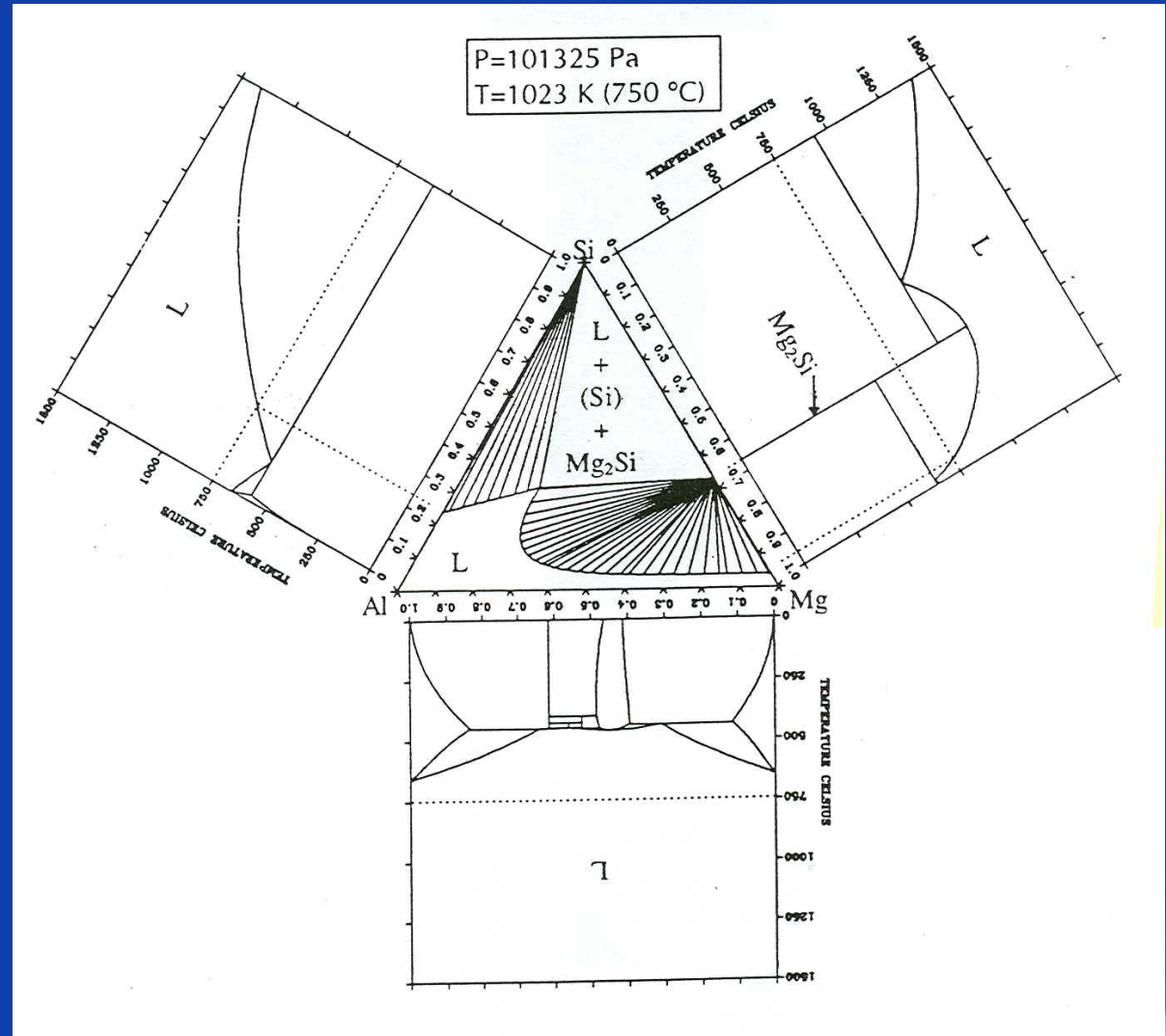


- Mission: develop a technique for calculating/predicting phase diagrams for multi-component multi-phase materials



- **STEP 1: Determine $G(T,p,x)$ expressions for all phases**
 - **Choice of a thermodynamic model**
 - **Determination of the parameters based on experimental and theoretical (a.o. ab-initio) input,**
 - **Such as phase equilibria, heat of formation, vapor pressures,**
....
- **STEP 2: Minimization of the total Gibbs energy of a multi-phase system**
 - **→ Phase diagrams**
 - **→ Thermodynamic quantities: chemical potential, heat of transformation, reaction, ...**
 - **→ Input for diffusion and microstructure simulations**

- E.g. Gibbs energies for ternary system
 - Pure elements, Al, Mg, Si
 - Binary systems, Al-Mg, Al-Si, Mg-Si
 - Ternary system, Al-Mg-Si



- **Choice of a standard element reference state (SER) for each element (reference structure, temperature and pressure)**

- **Temperature dependence Gibbs energy**

$$G - H_{SER} = a + bT + cT \ln(T) + dT^2 + e \frac{1}{T} + fT^3$$

$$\Rightarrow C_p = -c - 2dT - 2e \frac{1}{T^2} - 6fT^2 + \dots$$

– *a, b, c, d, ...* fitted to experiments, ab-initio data

- **Also models for magnetic ordering, effect of pressure**

- **General expression** $G - G^{ref} = G^{id} + G^{ex} + G^{phys}$
 - **Mechanical mixing of pure elements** $G^{ref,\alpha} = x_A G_A^{0,\alpha} + x_B G_B^{0,\alpha}$
 - **Ideal mixing (Raoult's solution)** $G^{id} = x_A \ln(x_A) + x_B \ln(x_B)$
 - **Redlich-Kister expression for excess interactions** $G^{ex,\alpha} = x_A x_B L_{AB}^v (x_A - x_B)^v$
 - T-dependenc of L_{AB}^v

$$L_{AB}^v = a + bT + cT \ln(T) + dT^2 + e \frac{1}{T} + fT^3$$
 - L_{AB}^v from experiments

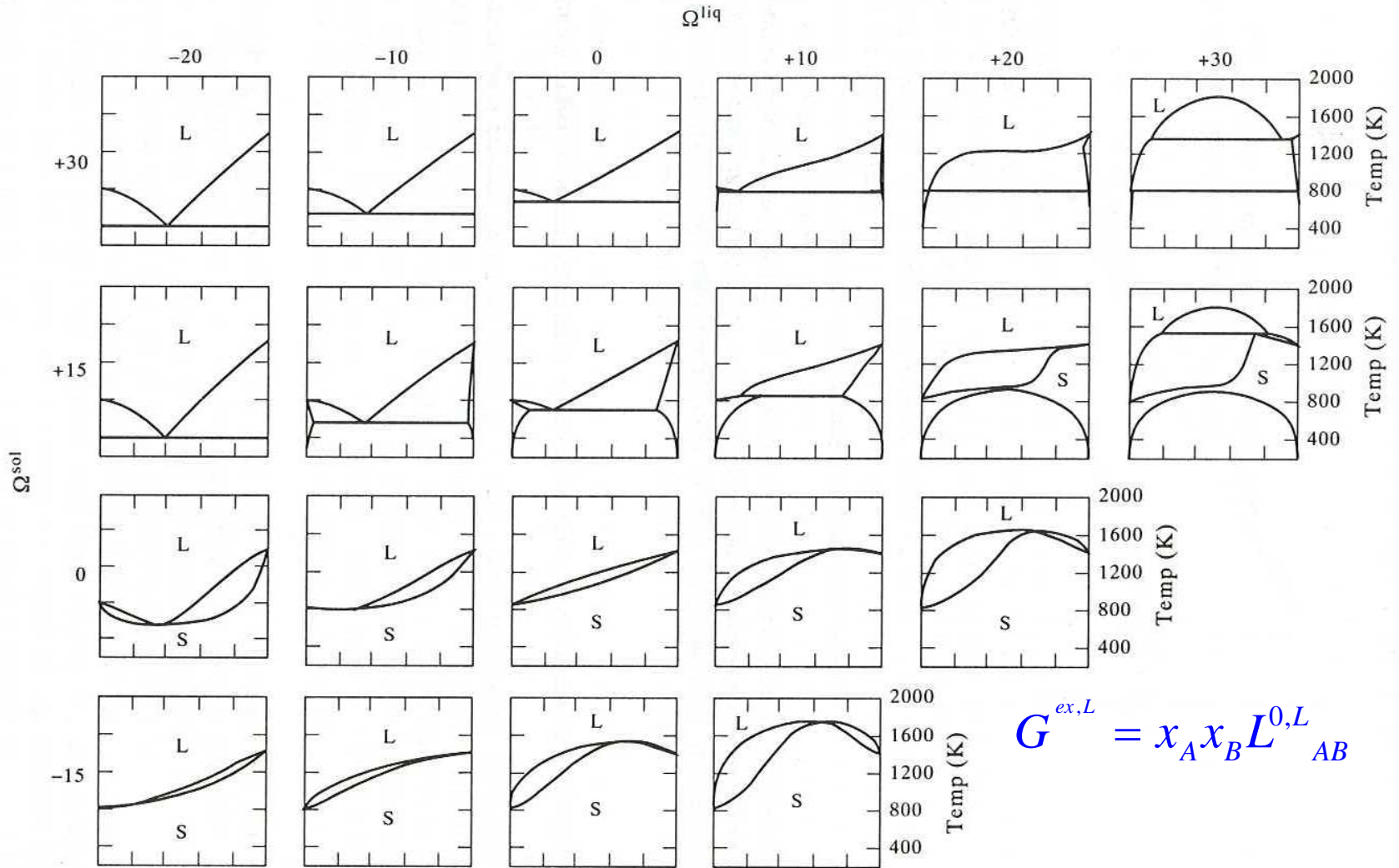


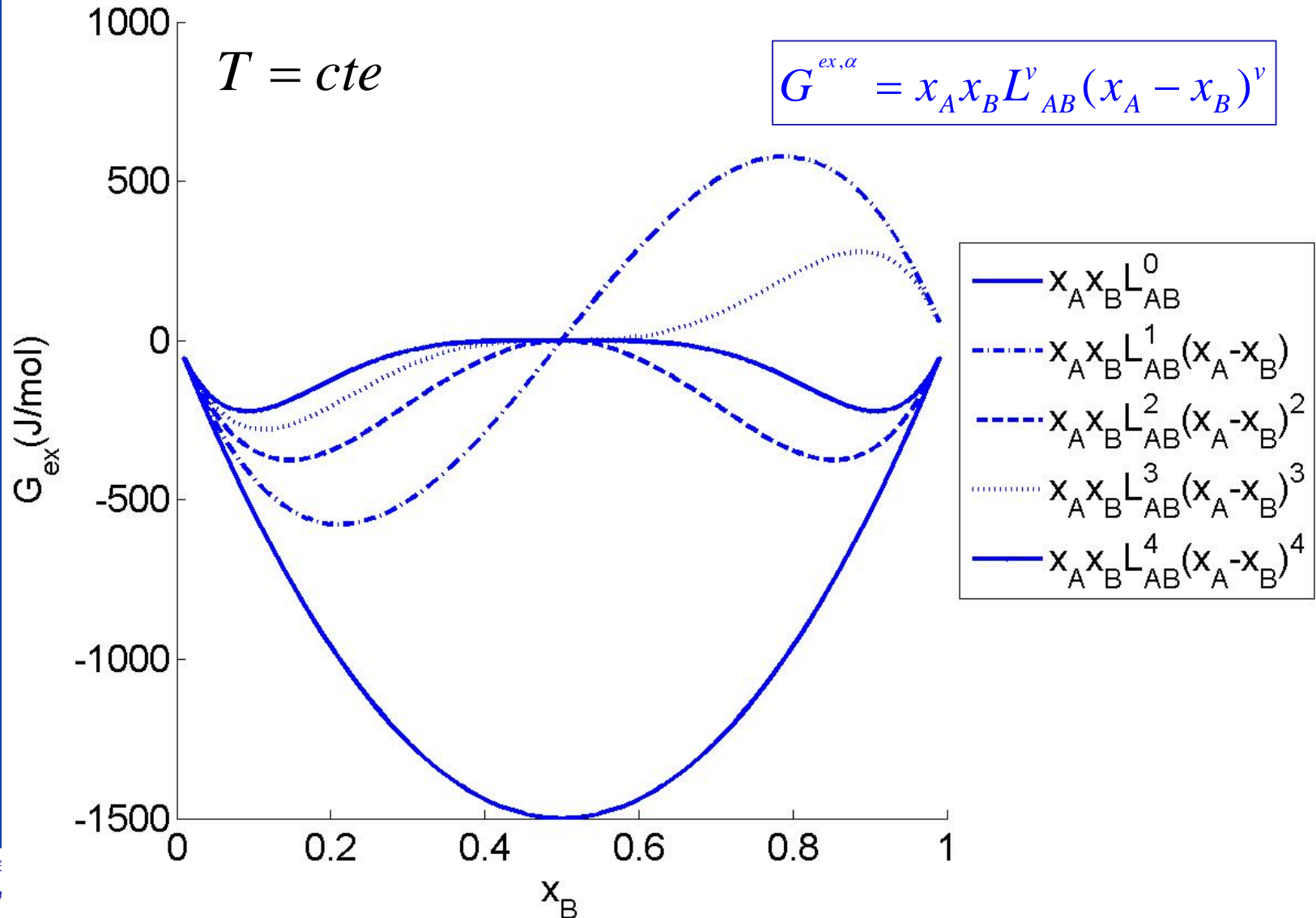
Figure 3.15. Topological features of phase diagrams calculated using regular solution theory.

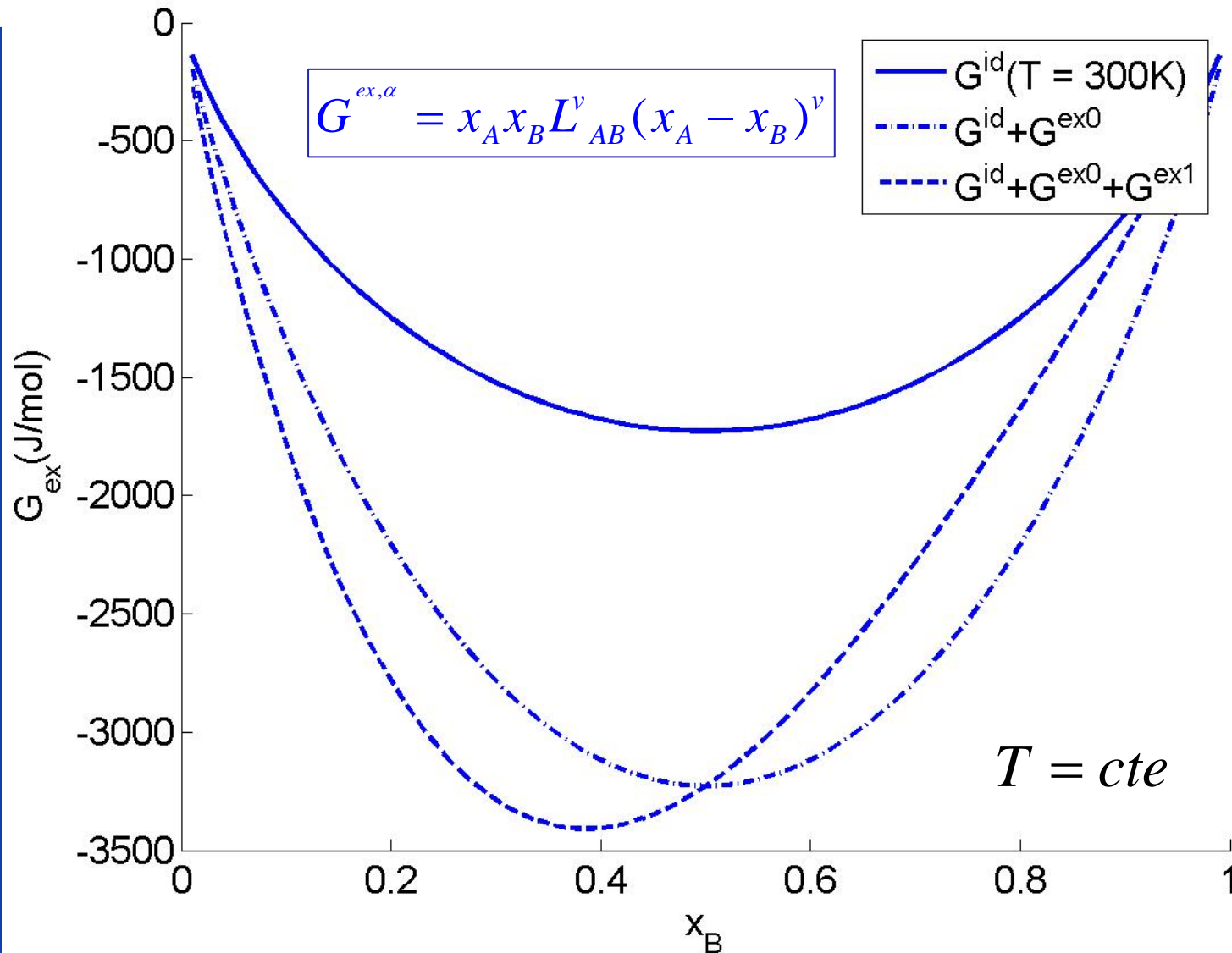
Illustration Redlich-Kister contributions

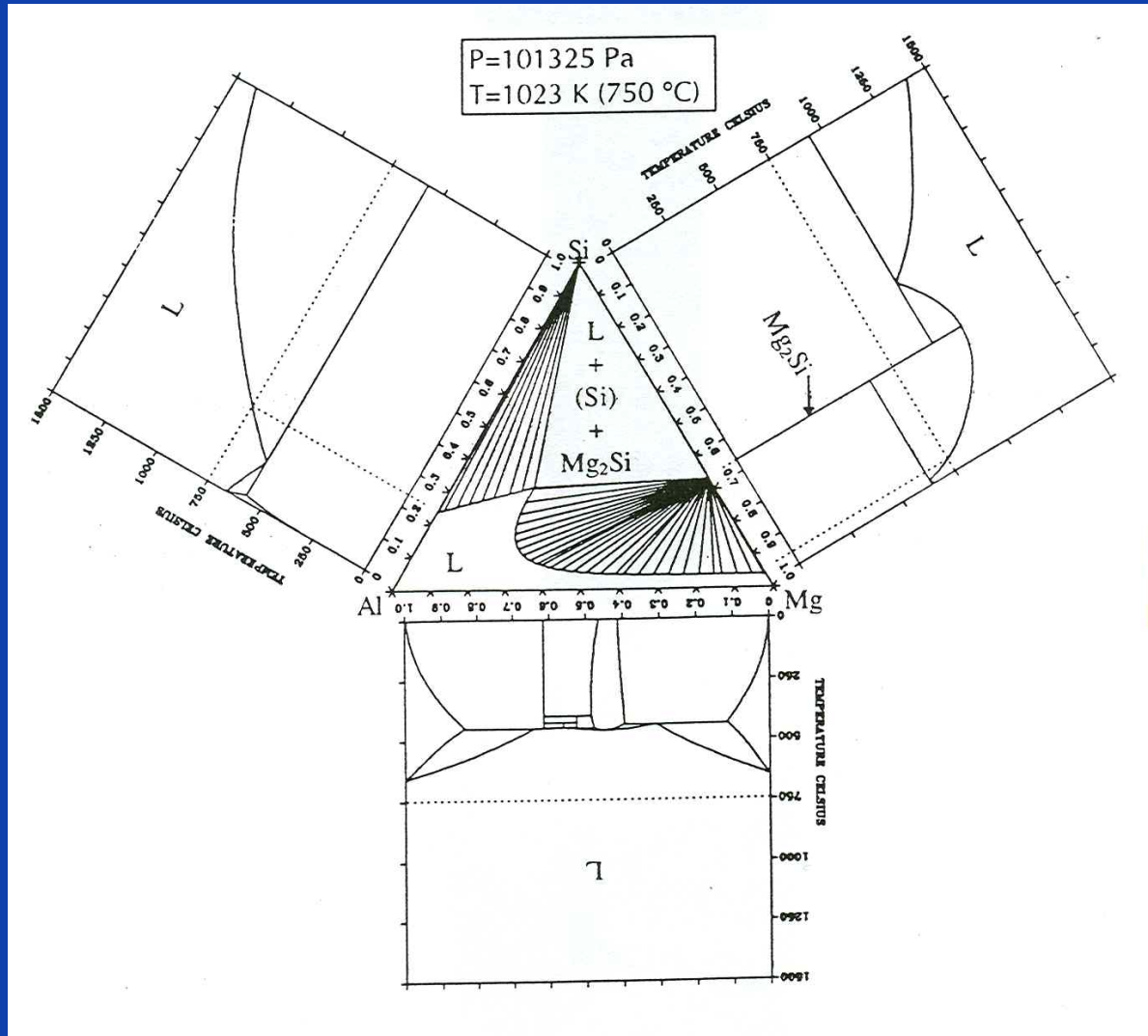
$$L_{AB}^0 = L_{AB}^1 = L_{AB}^2 = L_{AB}^3 = L_{AB}^4 = -6000$$

$T = cte$

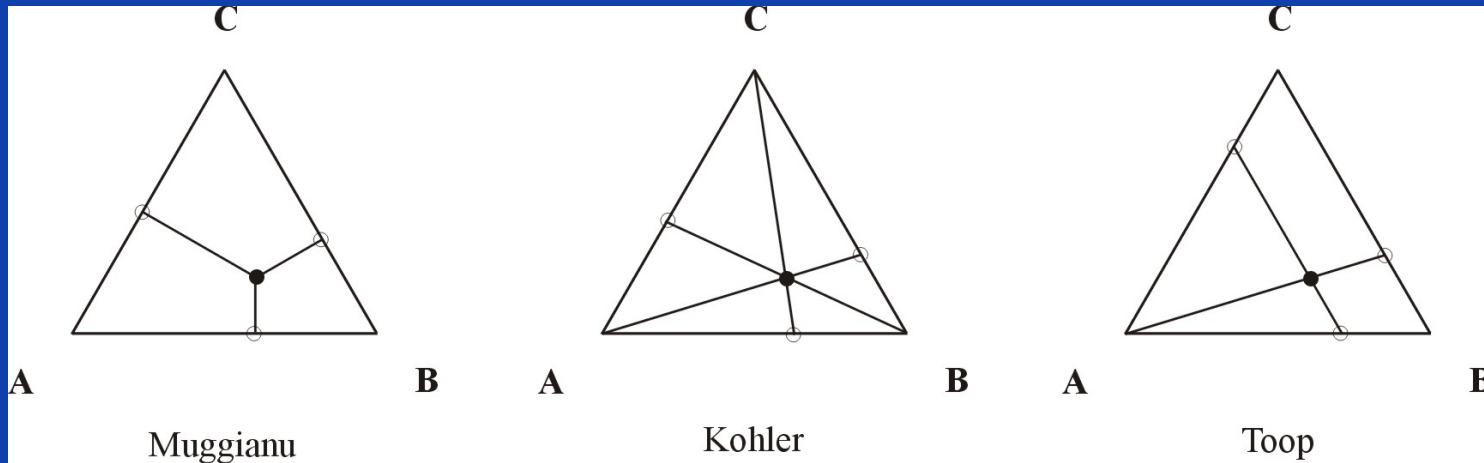
$$G^{ex,\alpha} = x_A x_B L_{AB}^v (x_A - x_B)^v$$







- Extrapolation schemes



- Redlich-Kister-Muggianu

$$G^{ex} = G_{AB}^{ex} + G_{AC}^{ex} + G_{BC}^{ex} + x_A x_B x_C (x_A L_{ABC}^0 + x_B L_{ABC}^1 + x_C L_{ABC}^2)$$

- **General expression** $G - G^{ref} = G^{id} + G^{ex} + G^{phys}$

- **Mechanical mixing of pure elements**

$$G^{ref,\alpha} = x_A G_A^{0,\alpha} + x_B G_B^{0,\alpha} + x_C G_C^{0,\alpha}$$

- **Ideal mixing (Raoult's solution)**

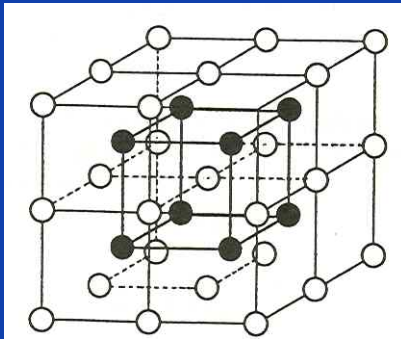
$$G^{id} = x_A \ln(x_A) + x_B \ln(x_B) + x_C \ln(x_C)$$

- **Excess interactions, Redlich-Kister-Muggianu**

$$G^{ex} = G_{AB}^{ex} + G_{AC}^{ex} + G_{BC}^{ex} + x_A x_B x_C (x_A L_{ABC}^0 + x_B L_{ABC}^1 + x_C L_{ABC}^2)$$

- **T-dependence** $L_{ABC}^v = a + bT$
- **G_{AB}^{ex} from binary optimizations**
- **L_{ABC}^v from experiments**

- **Phases with ordering**
 - Mixing only allowed within certain sublattices, represented as $(A,B)_{a1}(A,Va)_{a2}$



- Intermetallic compound, FeTi
 $\rightarrow (\%Fe, Ti)(Fe, \%Ti)$, Fe_2Ti
 $\rightarrow (\%Fe, Ti)_2(Fe, \%Ti)$, $B_2Ti \rightarrow (B)_2(Ti)$
- Interstitial phases,
 $(Cr, Fe, Ni, \dots)_{a1}(C, N, H, Va, \dots)_{a2}$

- Molar fraction \rightarrow *lattice fractions* $^1y_A, ^2y_A, ^1y_B, ^2y_{Va}$

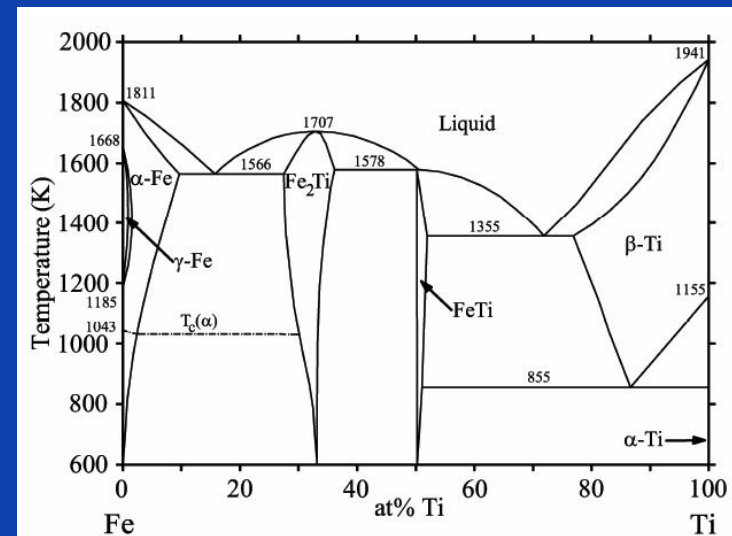
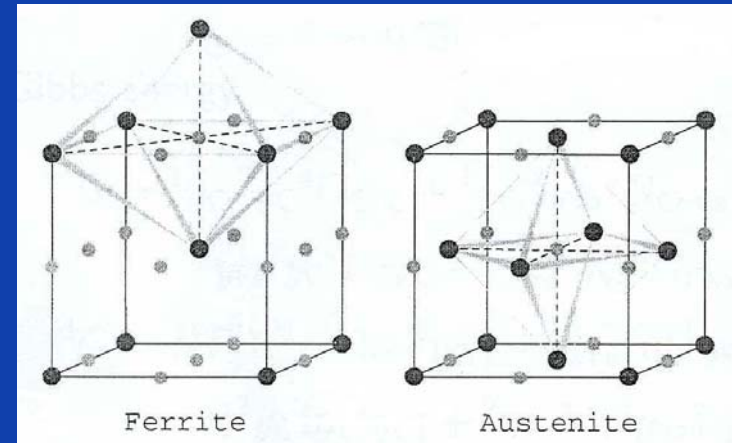


Figure 5.7: The calculated Fe-Ti phase diagram according to Hari Kumar [57]

***Quantitative and thermodynamically
consistent phase-field model for multi-phase
systems***

- **Single phase-field models -> Multiple phase-field models**

$$\eta \rightarrow \{\eta_1, \eta_2, \eta_3, \dots, \eta_p\}$$

$$(\eta_1, \eta_2, \dots, \eta_i, \dots, \eta_p) = (0, 0, \dots, 1, \dots, 0)$$

- **Model extension**

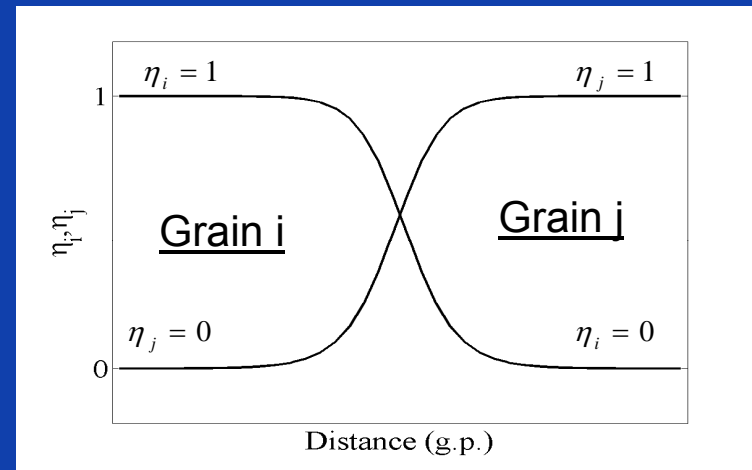
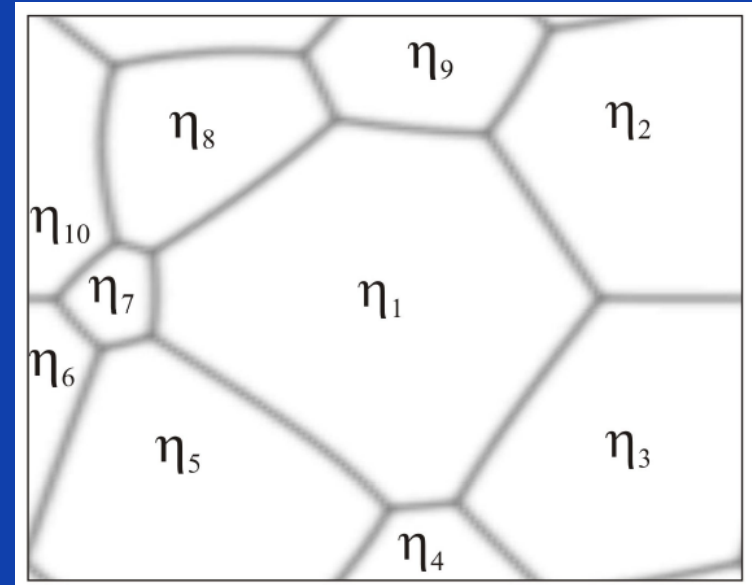
$$F(\eta_1, \eta_2, \eta_3, \dots, |\nabla \eta_1|^2, |\nabla \eta_2|^2, \dots)$$

- Different types of interfaces
- Triple and higher order junctions

- **Numerically**

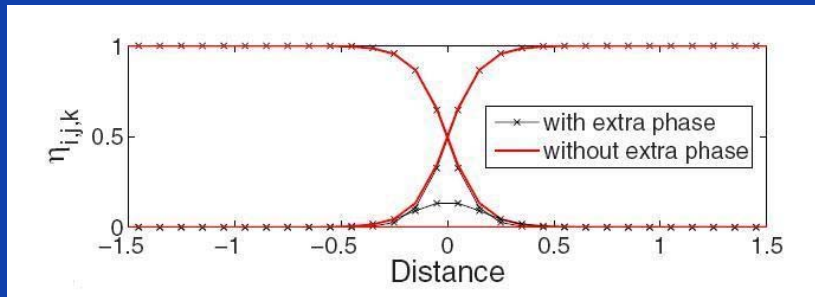
- Same accuracy for all interfaces and phases
- All interfaces within range of validity of the thin interface asymptotics

$$\rightarrow \ell_{num} = cte$$



- Third-phase contributions**

- $\sigma_{12} = \sigma_{13} = 7/10 \sigma_{12}$



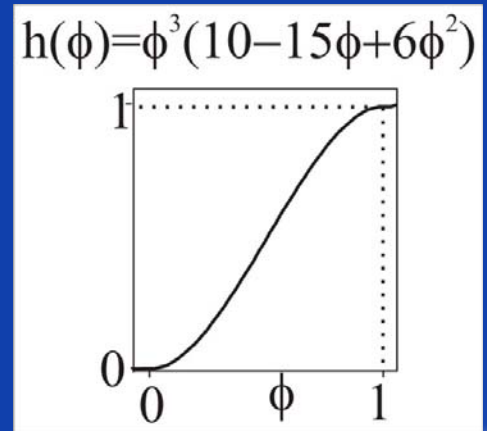
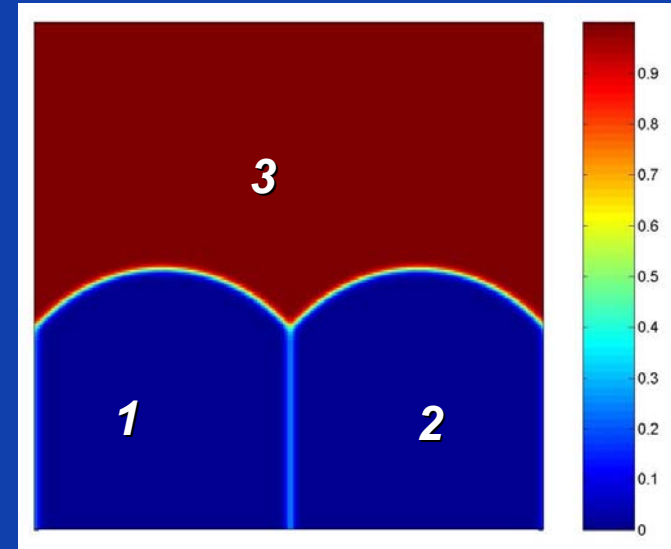
- Careful choice of multi-well function and gradient contribution

- Interpolation function**

- Zero-slope at equilibrium values of the phase fields
 - Thermodynamic consistency

$$f_{chem} = \sum_{i=1}^p h_i(\eta_1, \eta_2, \dots) f^i(c, T) \Rightarrow \sum_{i=1}^p h_i(\eta_1, \eta_2, \dots) = 1$$

η_3



Extension to multi-component multi-phase alloys

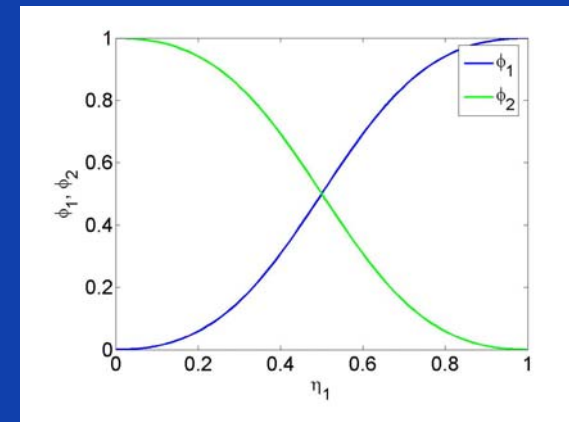
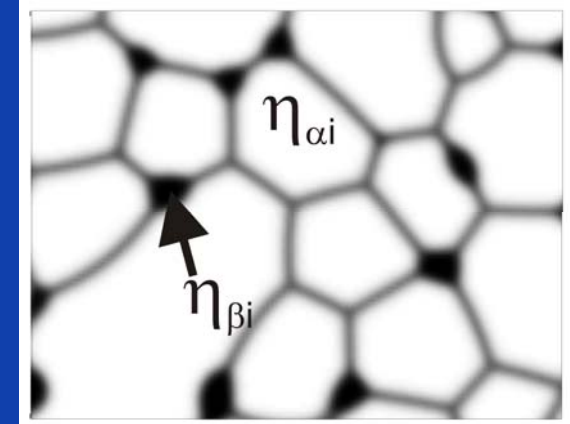
- Phase field variables:

- Grains $\eta_{\alpha 1}, \eta_{\alpha 2}, \dots, \eta_{\alpha i}(\vec{r}, t), \dots,$
- Composition $\eta_{\beta 1}, \eta_{\beta 2}, \dots, \eta_{\beta p}$
- Composition $c_A, c_B(\vec{r}, t), \dots, c_{C-1}$

- Bulk energy: $f_{bulk}(c_k, \eta_{\rho i}) = \sum_{\rho} \phi_{\rho} f^{\rho}(c_k^{\rho})$

- with

$$\left\{ \begin{array}{l} \frac{\partial f^{\beta}(c_k^{\beta})}{\partial c_k^{\beta}} = \frac{\partial f^{\alpha}(c_k^{\alpha})}{\partial c_k^{\alpha}} = \dots = \tilde{\mu}_k \\ x_k = \sum_{\rho} \phi_{\rho} x_k^{\rho} \end{array} \right. \quad \text{and} \quad \phi_{\rho} = \frac{\sum_i \eta_{\rho i}^2}{\sum_{\pi=\alpha, \beta, \dots} \sum_i \eta_{\pi i}^2}$$



N. Moelans, *Acta Mater.* 2011.

Extension to multi-component multi-phase alloys

- Bulk and interface diffusion:

$$\frac{\partial x_k}{\partial t} = \nabla \cdot \left[\left(\sum_{\rho} \phi_{\rho} M_k^{\rho} + \sum_{\rho, i \neq \sigma, j} \eta_{\rho, i}^2 \eta_{\sigma, j}^2 \right) \nabla \mu_k \right]$$

With

$$M_k^{\rho} = \frac{D_k^{\rho}}{\frac{\partial^2 f_m^{\rho}}{\partial x_k^2}}$$

and

$$M_{interf} = 3 \left(\frac{D_{interf}}{\partial^2 f^m / \partial x_k^2} \right) \left(\frac{\delta_{gb}}{\delta_{num}} \right)$$

- Interface movement:

$$\frac{\partial \eta_{i\rho}}{\partial t} = -L \frac{\delta F(\eta_{i\rho}, x_k)}{\delta \eta_{i\rho}}$$

- Between phase α and β

$$\frac{\partial \eta_{\alpha i}}{\partial t} = -L \left(\underbrace{g_{int}(\eta, \nabla \eta)}_{\text{Curvature driven}} - \frac{2\eta_{\alpha i} \eta_{\beta j}^2}{(\eta_{\alpha}^2 + \eta_{\beta}^2)^2} \underbrace{\left(f^{\alpha}(c^{\alpha}) - f^{\beta}(c^{\beta}) - (c^{\alpha} - c^{\beta})\mu \right)}_{\text{Bulk energy driven}} \right)$$

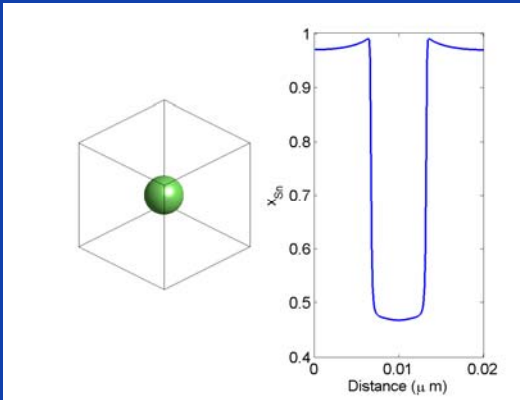
Curvature driven

Bulk energy driven

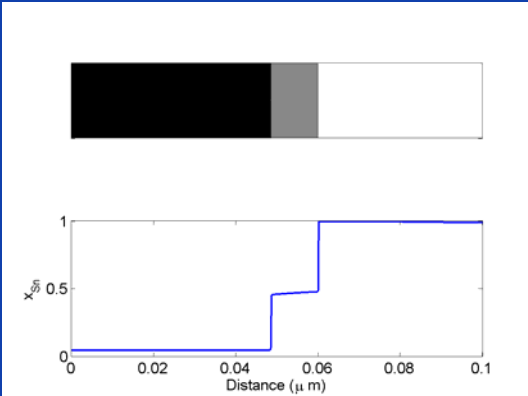
• Triple junction



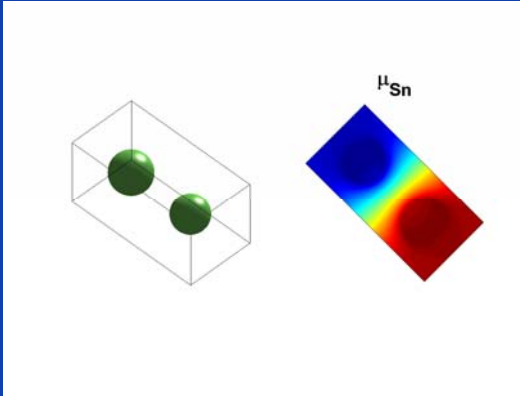
• Growing sphere



• Intermediate phase



• Coarsening



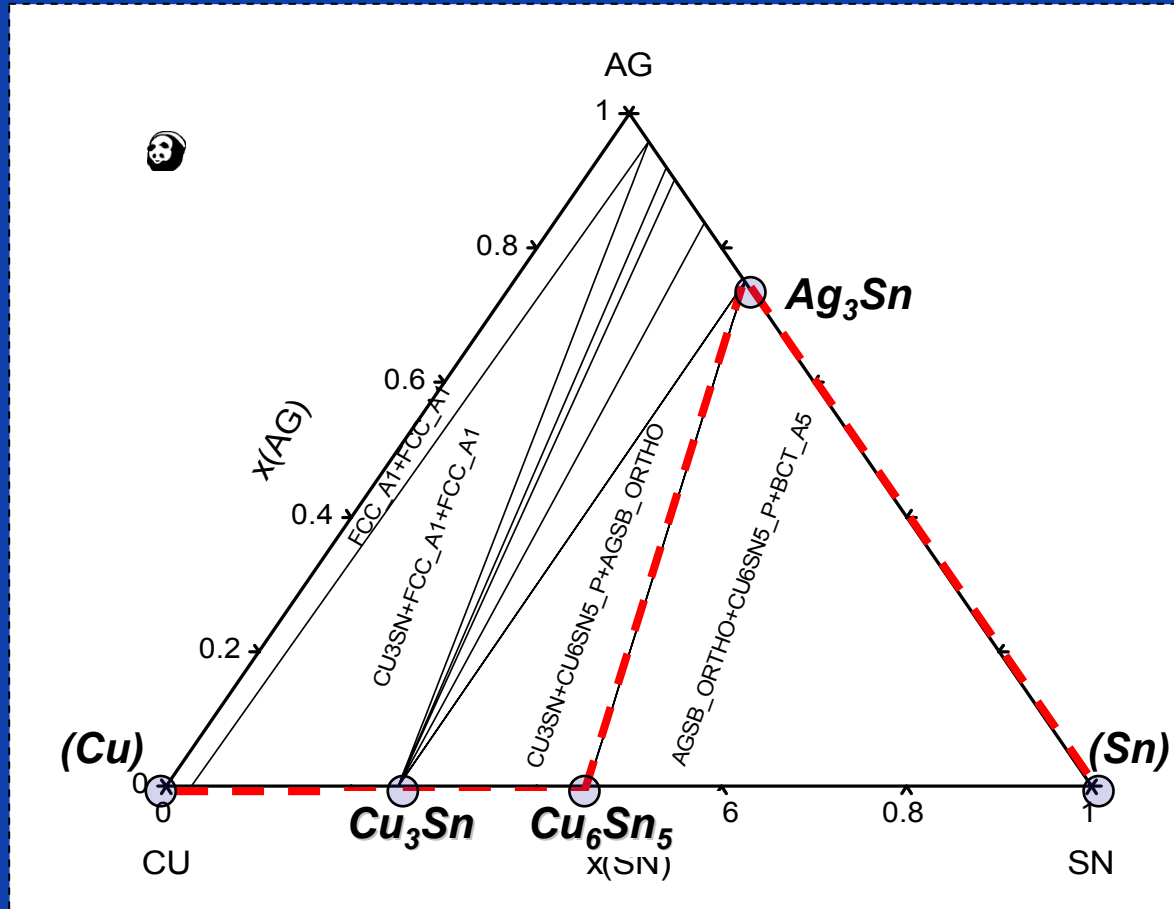
• Processes for which $v(t) \searrow$

- Conclusions for grain growth model remain
 - Accuracy controlled by $\ell_{num} / \Delta x$
 - Diffuse interface effects for $\ell_{num} / R > 5$
 - Angles outside $[100^\circ - 140^\circ]$ require larger resolution $\ell_{num} / \Delta x$ for same accuracy

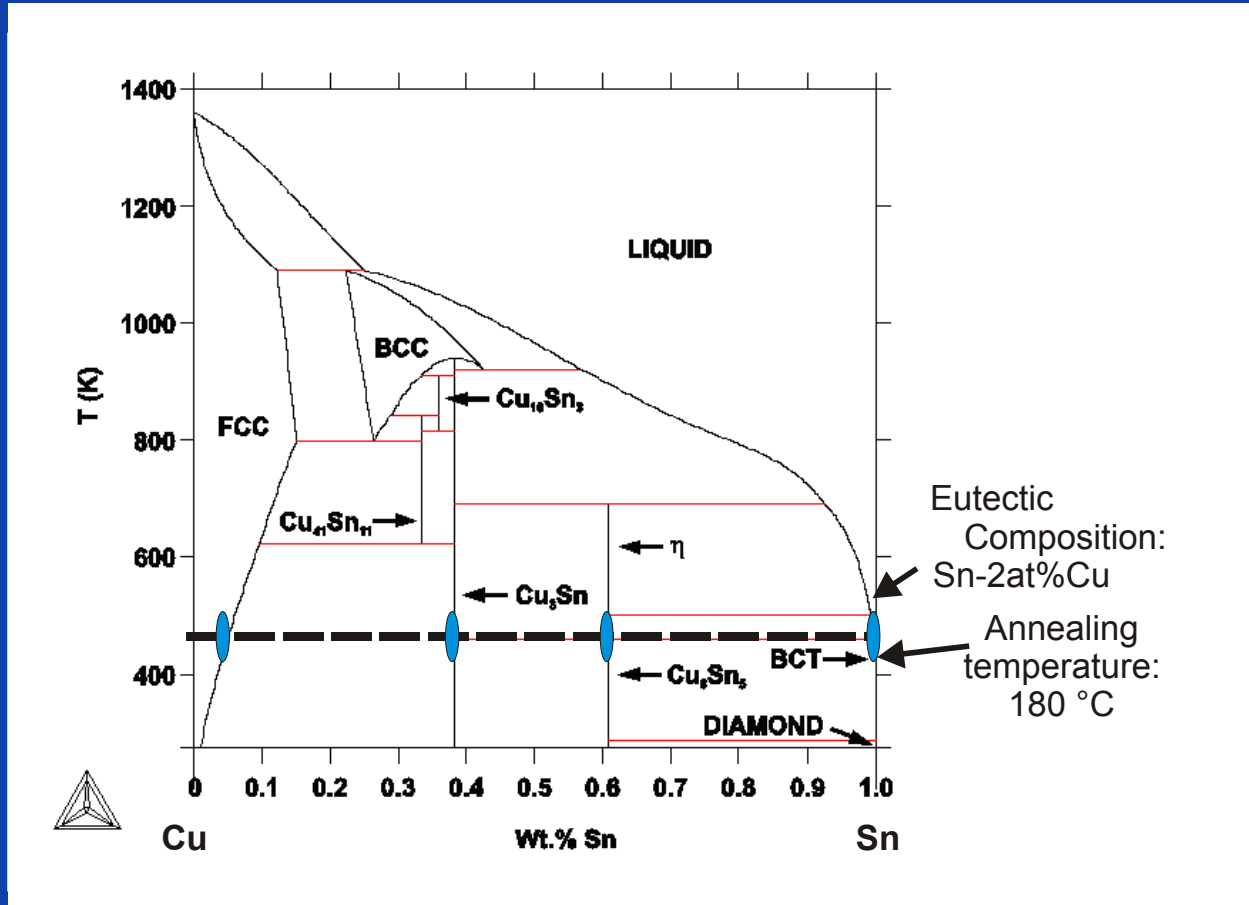
N. Moelans, *Acta Mater.* 2011.

Coupling phase-field with thermodynamics databases

- Ternary Ag-Cu-Sn, T = 180 °C



- Binary Cu-Sn



- Bulk energy** $f_{bulk}(\eta_i, x_{Sn}) = \sum_{\rho} \phi_{\rho} f^{\rho}(x_{Sn}^{\rho}) = \sum_{\rho} \phi_{\rho} \frac{G_m^{\rho}(x_{Sn}^{\rho})}{V_m}$

- Parabolic composition dependence**

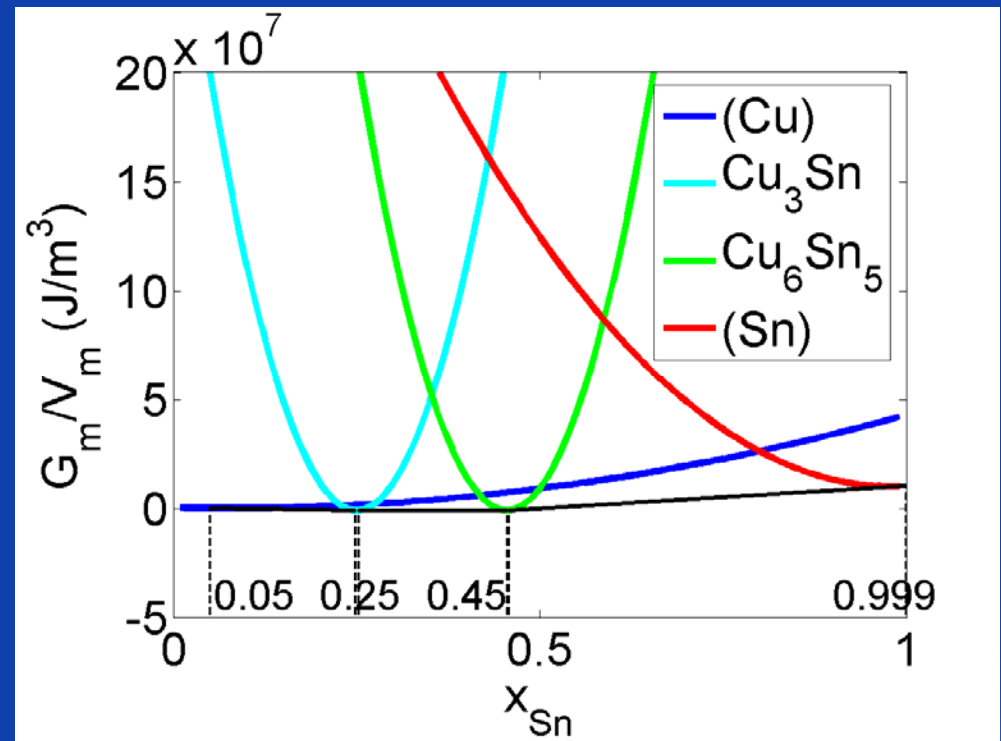
$$f^{\rho} = \frac{A^{\rho}}{2} (x_{Sn} - x_{Sn,0})^2 + C^{\rho}$$

- Simplifies solution phase-field equations

- No composition dependence needed for D

$$M^{\rho} = \frac{D^{\rho}}{\frac{\partial^2 f^{\rho}}{\partial x_{Sn}^2}} = \frac{D^{\rho}}{A^{\rho}}$$

- Difficult for higher order systems and large composition variations



S.Y. Hu, J. Murray, H. Weiland, Z.-K. Liu, L.-Q. Chen, *Comp. Coupl. Phase Diagr. Thermoch.*, 31 (2007) p 303

- Free energies over full composition range are needed in phase-field

- Stoichiometric phases**

- Approximated as

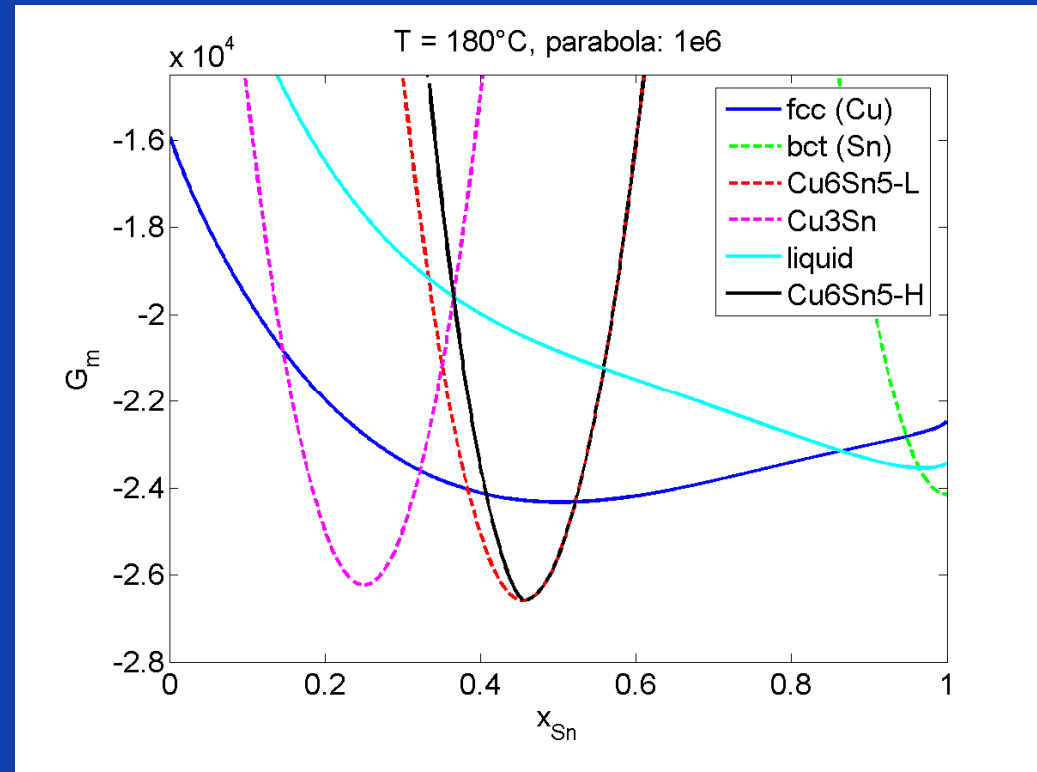
$$G^p = \frac{A^p}{2} (x_{Sn} - x_{Sn,0})^2 + C^p$$

$$C^p = G^{stoich}$$

$$x_{Sn,0} = x_{stoich}$$

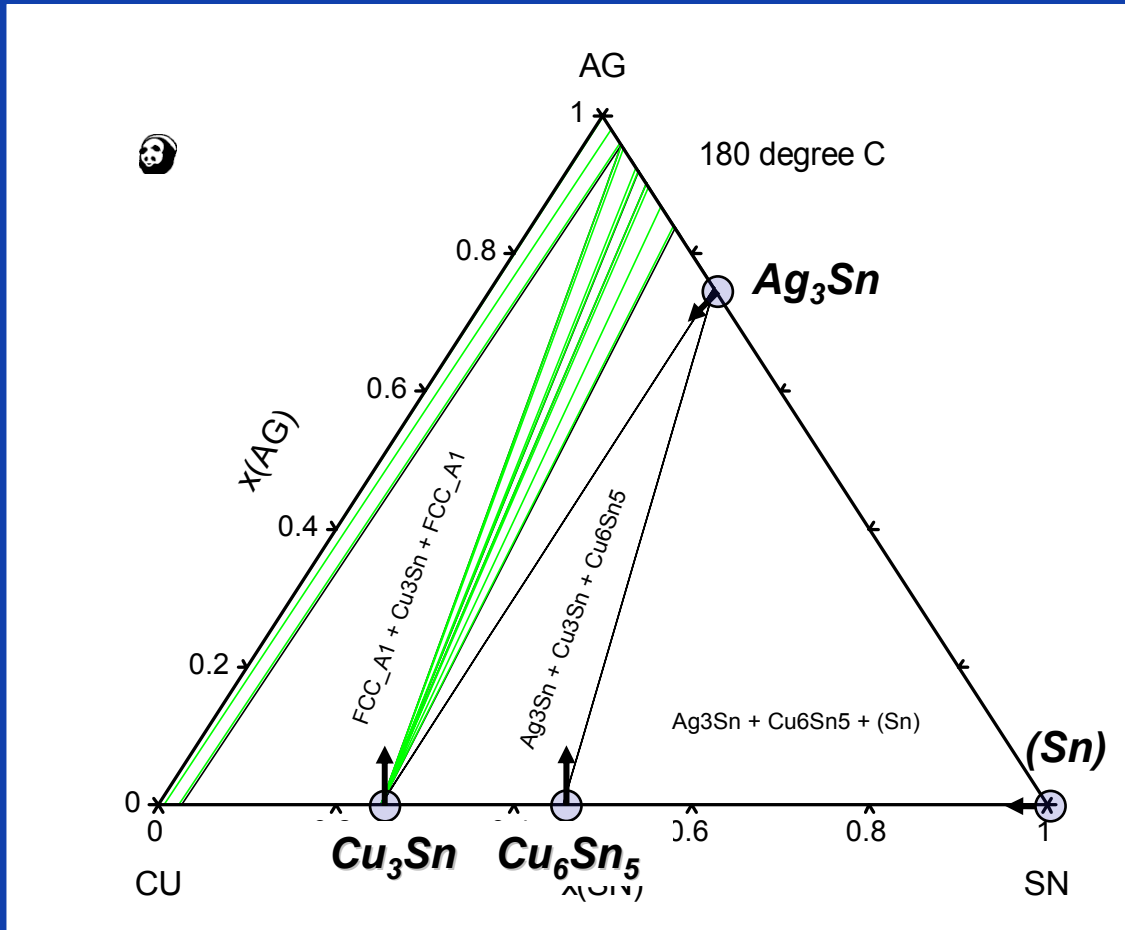
- Choice of A requires ‘trial and error’
 - Numerics – Small shift in phase equilibria
 - Here: $A = 1^6$

Cu-Sn



Gibbs energies from A. Dinsdale, A. Watson, A. Kroupa, J. Vřešťál, A. Zemanová, J. Vízdal COST 531-Lead Free Solders: Atlas of Phase Diagrams for Lead-Free Soldering, vols. 1,2 (2008) ESC-Cost office

Ag-Cu-Sn



- Binary phases shifted into ternary, e.g.

$$G^{Ag_3Sn} = G^{Ag_3Sn}(x'_{Ag}, x'_{Sn}) + \frac{A}{2}(x_{Sh} - x_{Cu})^2$$

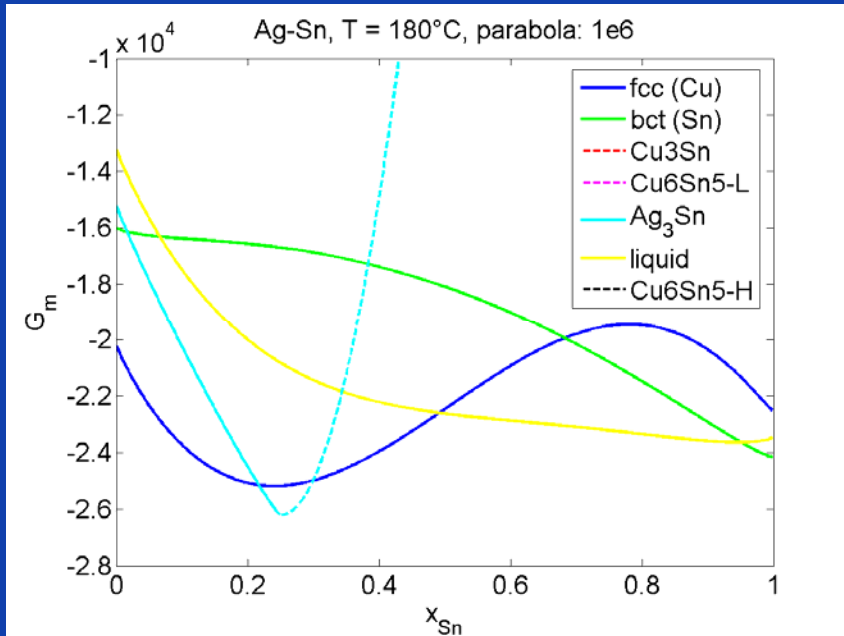
With

$$x'_{Ag} = (1 - x_{Sh})x_{Ag}$$

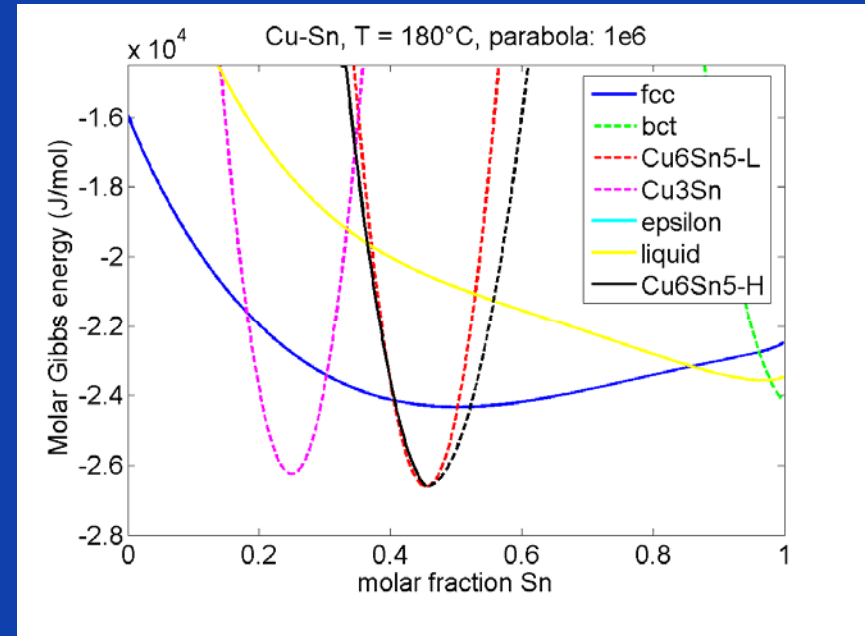
$$x'_{Sn} = (1 - x_{Sh})x_{Sn}$$

$$A = 1e6$$

$$x_{Sh} = 0.001$$



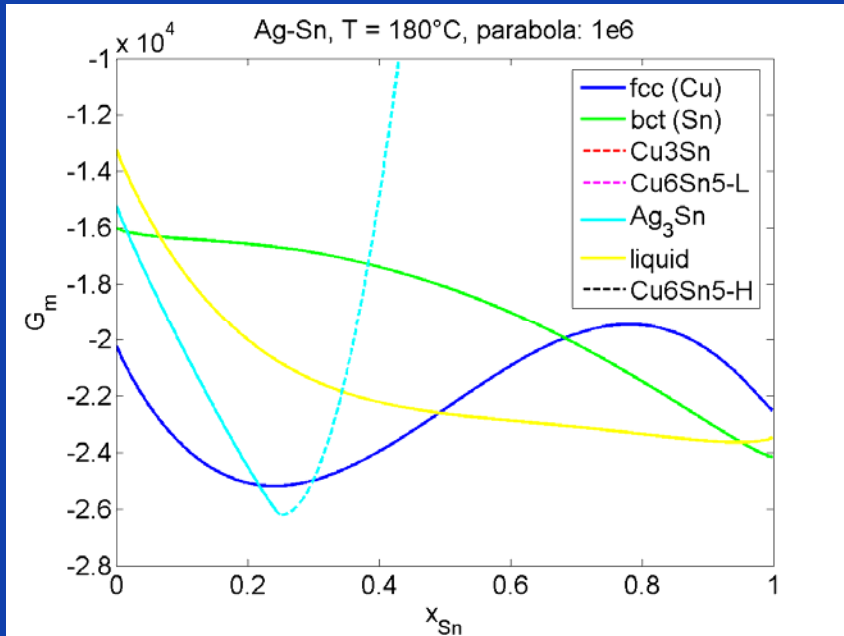
Ag-Sn-0.001Cu



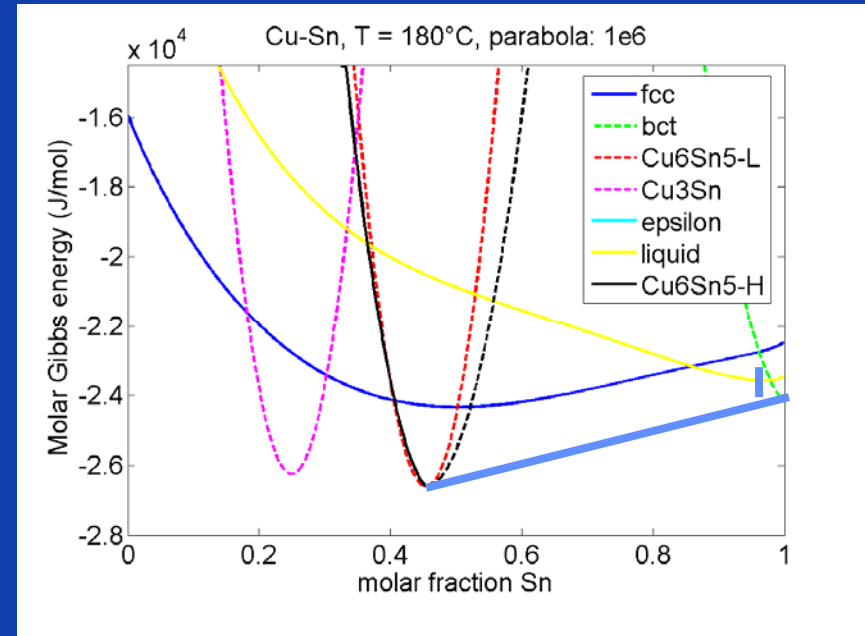
Cu-Sn-0.001Ag

- **Sublattice model + parabolic extension**





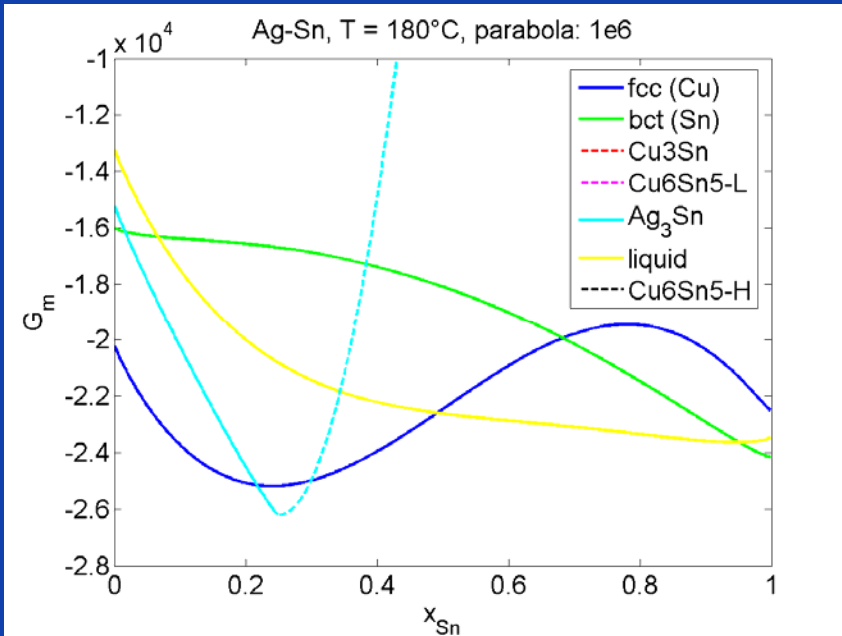
Ag-Sn-0.001Cu



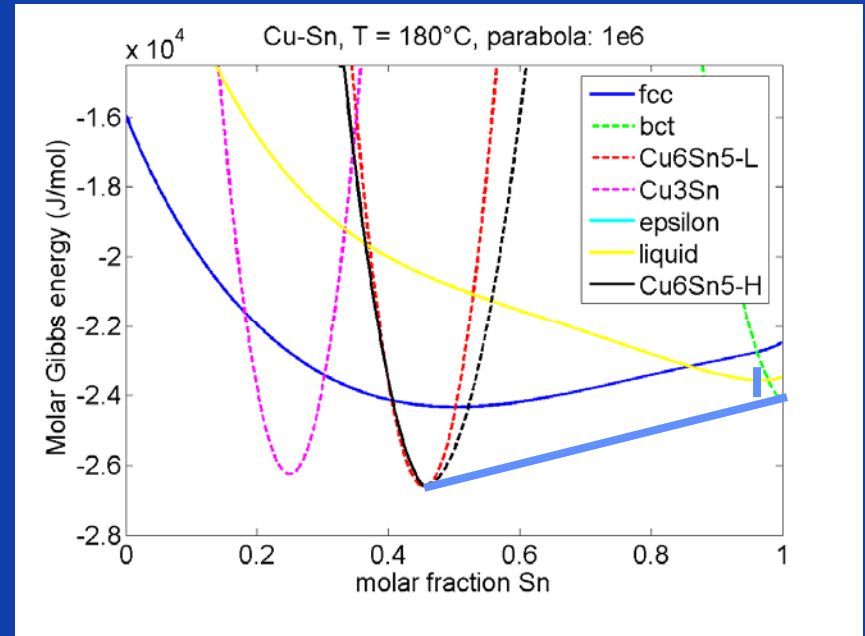
Cu-Sn-0.001Ag

- **Sublattice model + parabolic extension**





Ag-Sn-0.001Cu



Cu-Sn-0.001Ag

• **Sublattice model + parabolic extension**

• **Cu₆Sn₅-H:** (Cu)_{.545}·(Cu,Sn)_{.122}·(Sn)_{.333}

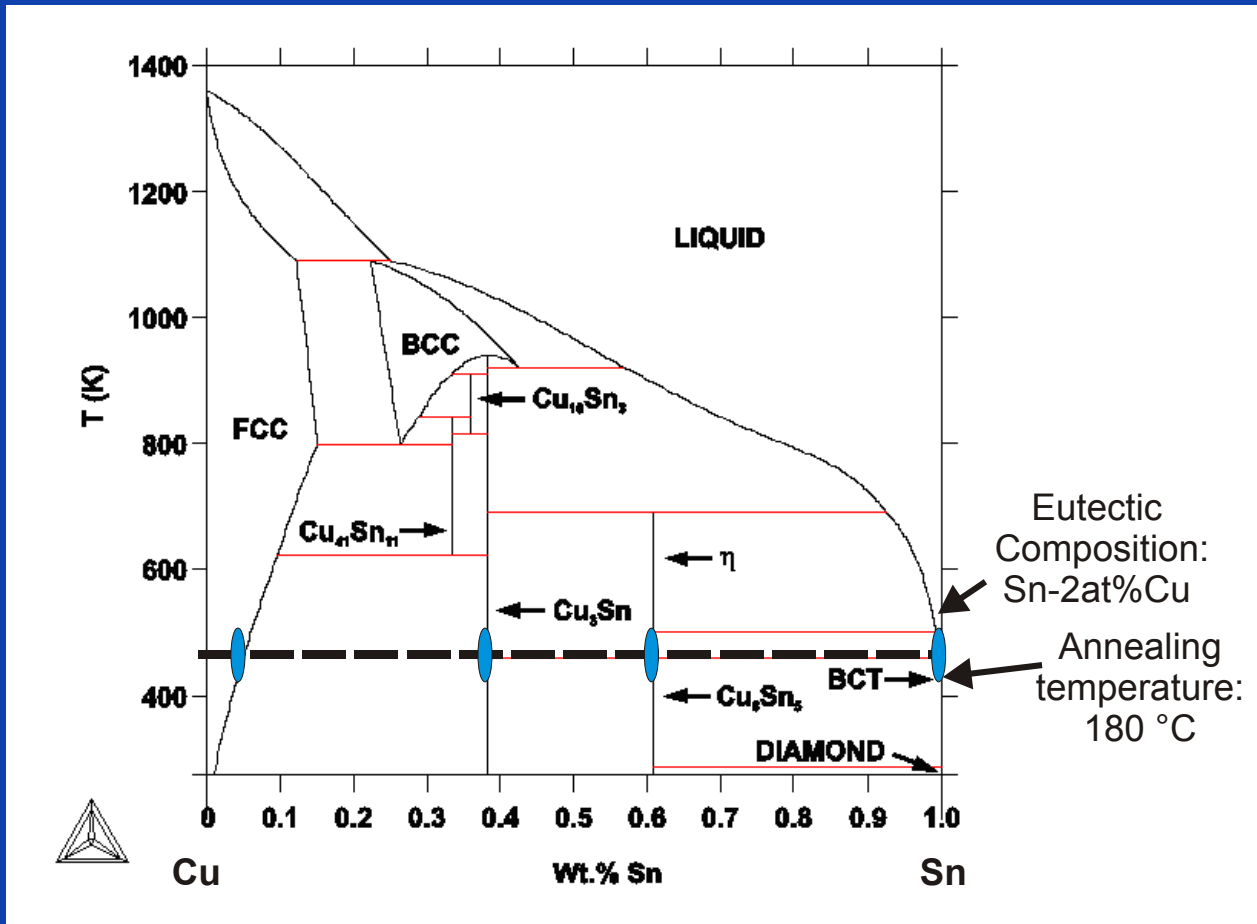
• **Ag₃Sn:** (Ag)_{.75}(Ag,Sn)_{.25}

→ $G^P(x_{Ag}, x_{Cu}, x_{Sn})$ over full composition range

Interdiffusion and intermetallic growth in Cu/Sn-Cu solder joints

- **Equilibrium compositions**

- **Interdiffusion coefficients**



$$D_{\text{Sn}}^{(\text{Cu})} = 10^{-25}$$

$$D_{\text{Sn}}^{\text{Cu}_3\text{Sn}} = 5 \cdot 10^{-16} \text{ m}^2/\text{s}$$

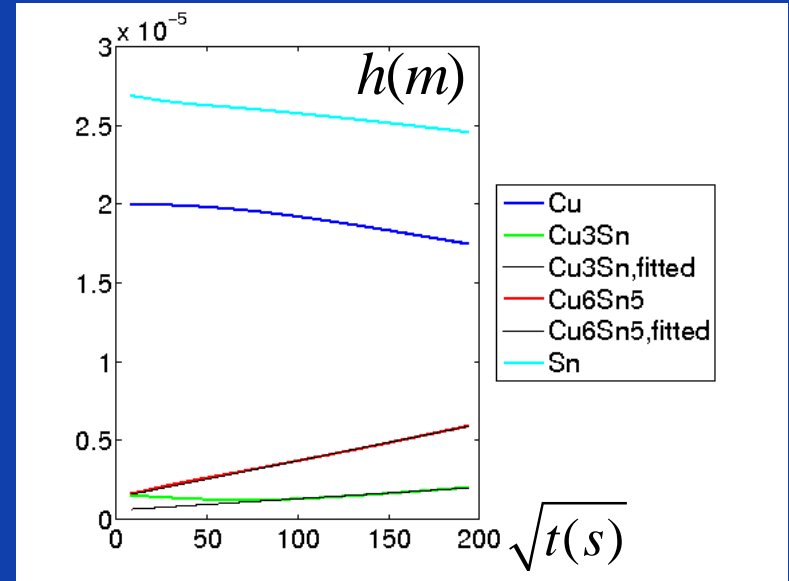
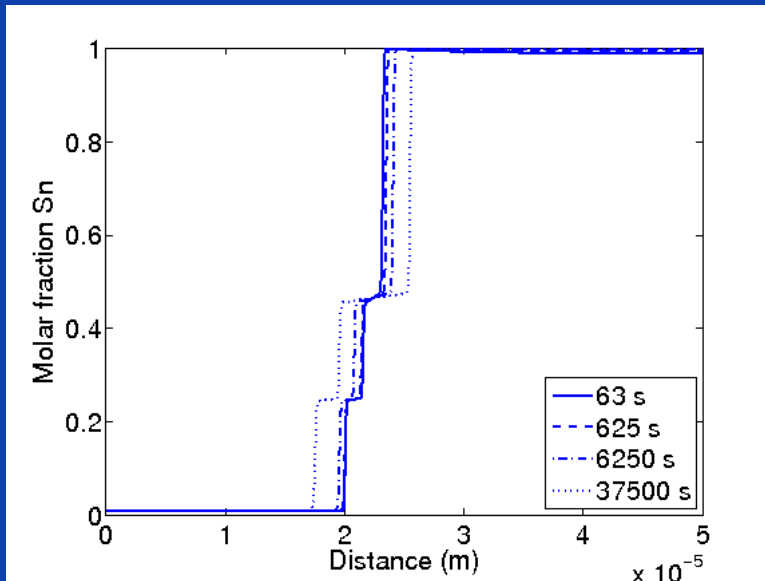
$$D_{\text{Sn}}^{\text{Cu}_6\text{Sn}_5} = 10^{-15} \text{ m}^2/\text{s}$$

$$D_{\text{Sn}}^{(\text{Sn})} = 10^{-12} \text{ m}^2/\text{s}$$

- **Interfacial energy**

$$\gamma_{gb} = 0.25 \text{ J/m}^2$$

- Effect of bulk diffusion coefficients



Diffusion coefficients

$$D_{Sn}^{(Cu)} = 10^{-25} \text{ m}^2/\text{s}$$

$$D_{Sn}^{Cu3Sn} = 10^{-14} \text{ m}^2/\text{s}$$

$$D_{Sn}^{Cu6Sn5} = 10^{-14} \text{ m}^2/\text{s}$$

$$D_{Sn}^{(Sn)} = 10^{-12} \text{ m}^2/\text{s}$$

Initial composition

$$x_{Sn,0}^{(Cu)} = 0.01 (< x_{Sn,eq}^{(Cu)})$$

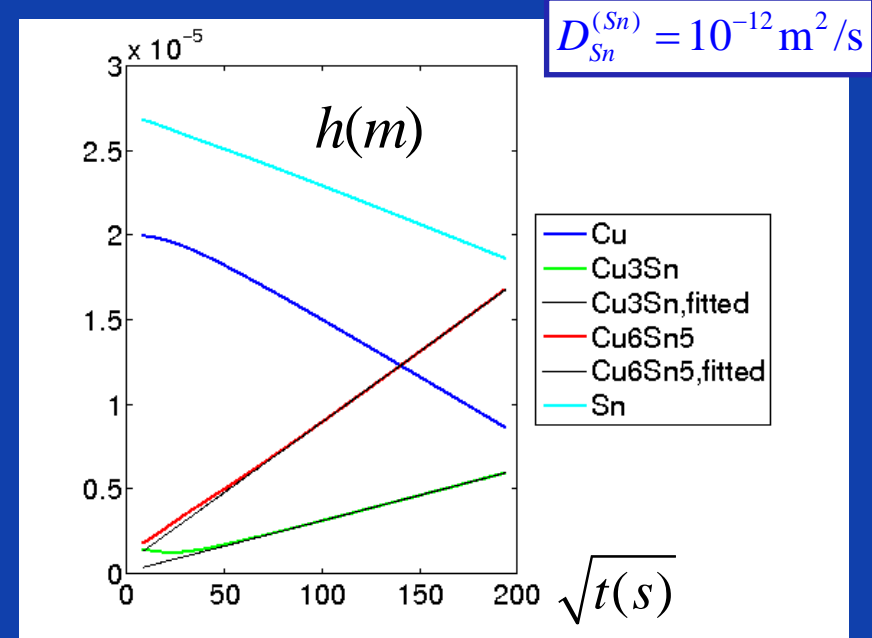
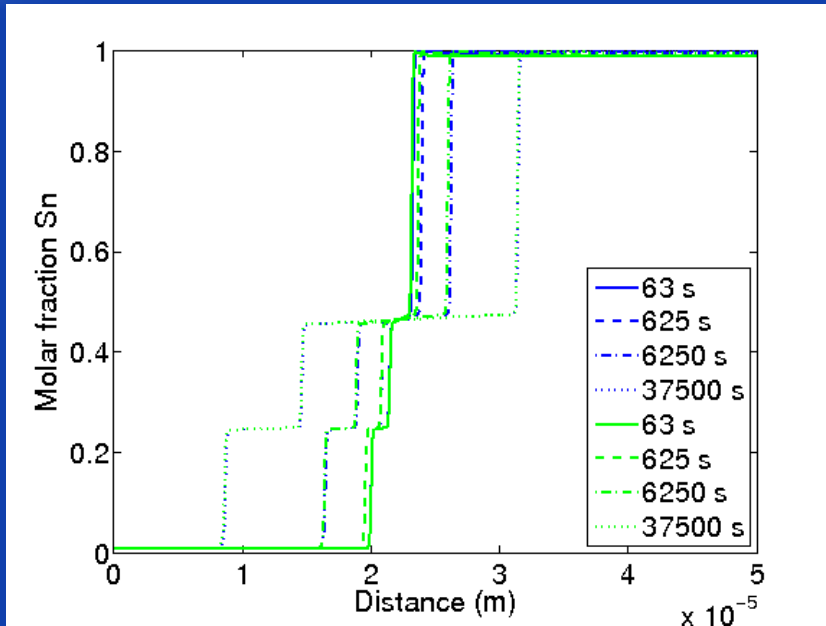
$$x_{Sn,0}^{Cu3Sn} = 0.25$$

$$x_{Sn,0}^{Cu6Sn5} = 0.455$$

$$x_{Sn,0}^{(Sn)} = 0.99 (< x_{Sn,eq}^{(Sn)})$$

$$\Rightarrow k_{Cu3Sn} = 0.0073 \cdot 10^{-6}$$

$$k_{Cu6Sn5} = 0.023 \cdot 10^{-6}$$



$$D_{Sn}^{(Cu)} = 10^{-25} \text{ m}^2 / \text{s}$$

$$D_{Sn}^{Cu3Sn} = 10^{-13} \text{ m}^2 / \text{s}$$

$$D_{Sn}^{Cu6Sn5} = 10^{-13} \text{ m}^2 / \text{s}$$

$$D_{Sn}^{(Sn)} = 10^{-12} \text{ m}^2 / \text{s}$$

$$D_{Sn}^{(Cu)} = 10^{-25} \text{ m}^2 / \text{s}$$

$$D_{Sn}^{Cu3Sn} = 10^{-13} \text{ m}^2 / \text{s}$$

$$D_{Sn}^{Cu6Sn5} = 10^{-13} \text{ m}^2 / \text{s}$$

$$D_{Sn}^{(Sn)} = 10^{-14} \text{ m}^2 / \text{s}$$

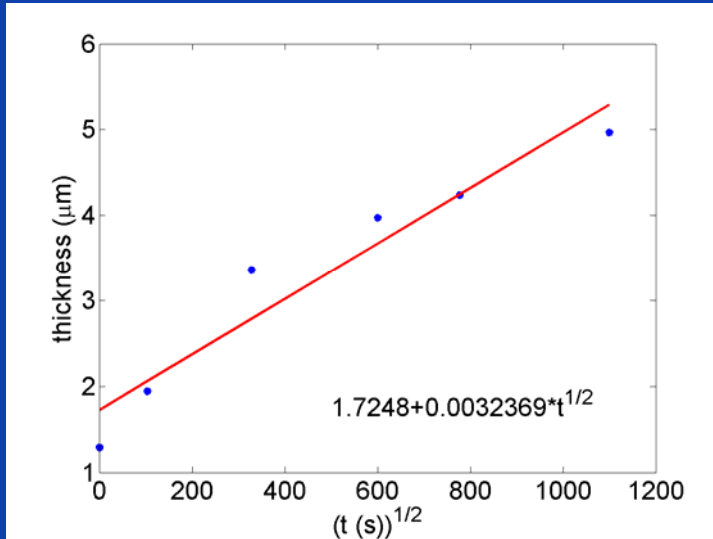
$$\Rightarrow k_{Cu3Sn} = 0.0301 \cdot 10^{-6}$$

$$k_{Cu6Sn5} = 0.0833 \cdot 10^{-6}$$

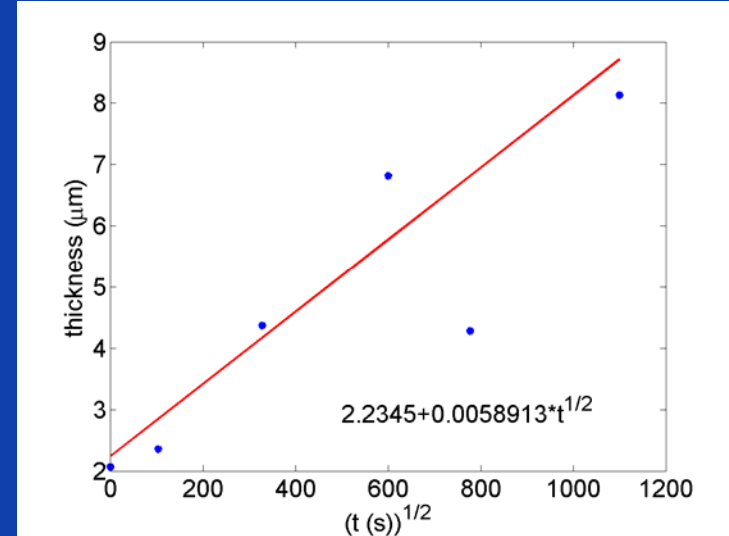
$$\Rightarrow k_{Cu3Sn} = 0.0306 \cdot 10^{-6}$$

$$k_{Cu6Sn5} = 0.0849 \cdot 10^{-6}$$

Cu_3Sn , $T = 180\text{ }^\circ\text{C}$



Cu_6Sn_5 , $T = 180\text{ }^\circ\text{C}$



Parabolic growth constant experiments

T	k_{Cu_3Sn}	$k_{Cu_6Sn_5}$
150 °C	0.0010 10^{-6}	0.00032 10^{-6}
180 °C	0.0032 10^{-6}	0.0059 10^{-6}
200 °C	0.0043 10^{-6}	0.0071 10^{-6}

Parabolic growth constant in simulations with

$$D_{Sn}^{(Cu)} = 10^{-25} \text{ m}^2/\text{s} \quad \Rightarrow \quad k_{Cu_3Sn} = 0.0023 \cdot 10^{-6}$$

$$D_{Sn}^{Cu_3Sn} = 10^{-15} \text{ m}^2/\text{s} \quad \Rightarrow \quad k_{Cu_6Sn_5} = 0.0073 \cdot 10^{-6}$$

$$D_{Sn}^{Cu_6Sn_5} = 10^{-15} \text{ m}^2/\text{s}$$

$$D_{Sn}^{(Sn)} = 10^{-12} \text{ m}^2/\text{s}$$

Data from J. Janckzak, EMPA

- 2D simulations**

$$D_{Sn}^{(Cu)} = 10^{-25} \text{ m}^2/\text{s}$$

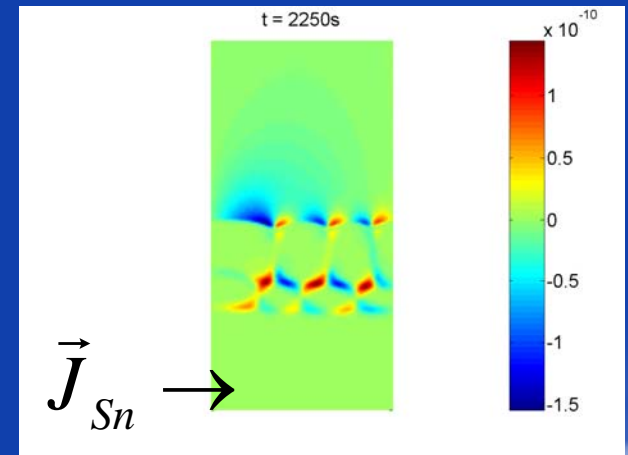
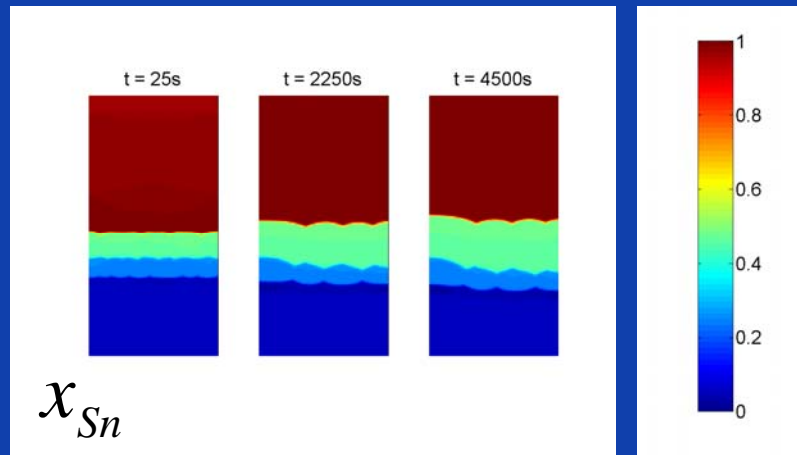
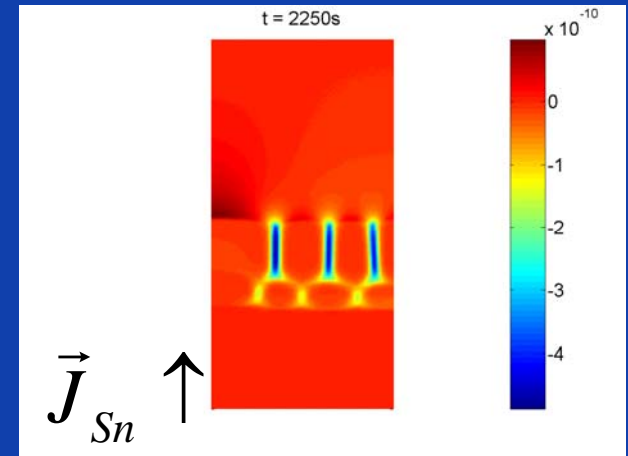
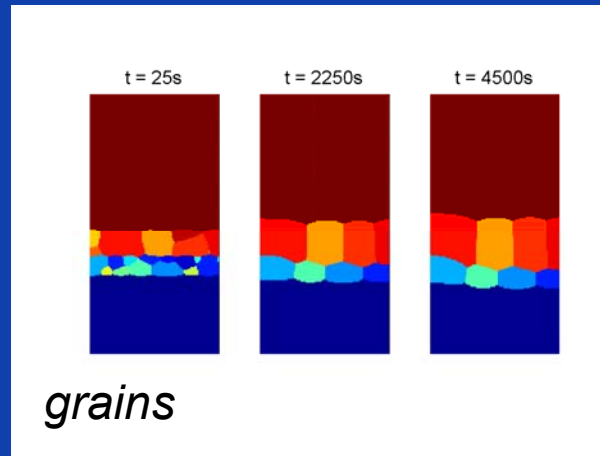
$$D_{Sn}^{Cu3Sn} = 10^{-15} \text{ m}^2/\text{s}$$

$$D_{Sn}^{Cu6Sn5} = 10^{-15} \text{ m}^2/\text{s}$$

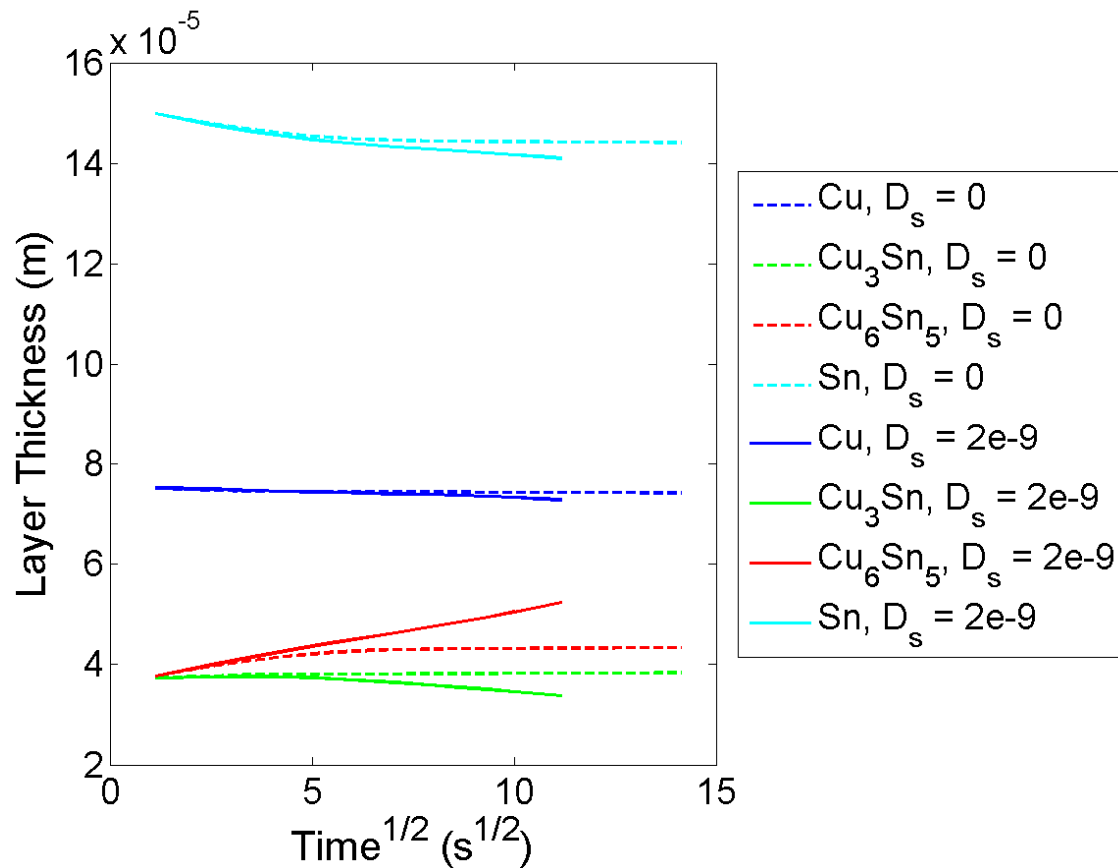
$$D_{Sn}^{(Sn)} = 10^{-12} \text{ m}^2/\text{s}$$

$$D_{Sn}^{surf} = 0.66 \cdot 10^{-9} \text{ m}^2/\text{s}$$

$$\delta_{gb} = 1 \text{ nm}$$



- 3D simulations**



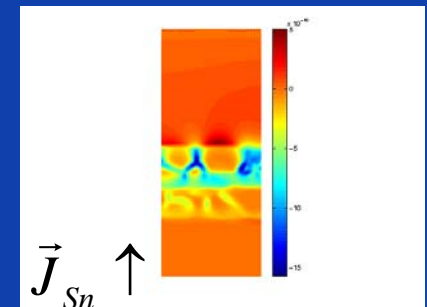
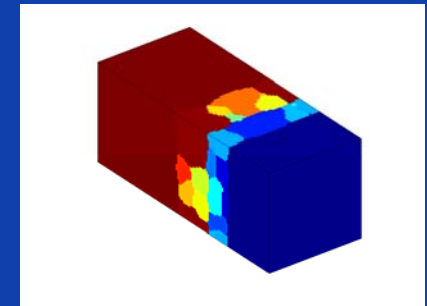
$$D_{Sn}^{(Cu)} = 2 \cdot 10^{-25} \text{ m}^2/\text{s}$$

$$D_{Sn}^{Cu_3Sn} = 2 \cdot 10^{-15} \text{ m}^2/\text{s}$$

$$D_{Sn}^{Cu_6Sn_5} = 2 \cdot 10^{-15} \text{ m}^2/\text{s}$$

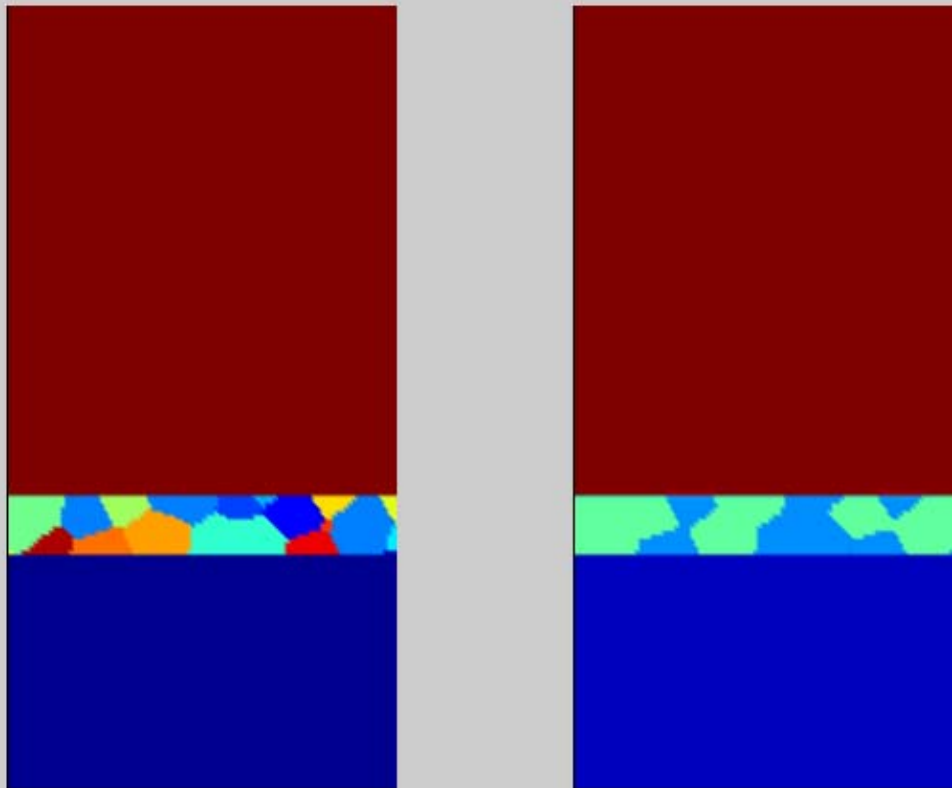
$$D_{Sn}^{(Sn)} = 2 \cdot 10^{-12} \text{ m}^2/\text{s}$$

$$D_{interf} = 2 \cdot 10^{-9} \text{ m}^2/\text{s} \quad \delta_{gb} = 1 \text{ nm}$$



Grain structure

Composition: x_{Sn}



time:0 sec

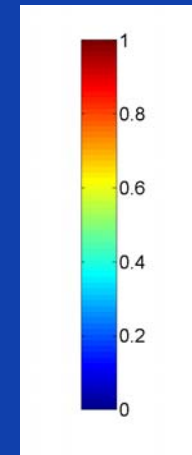
$$D_{\text{Sn}}^{(\text{Cu})} = 2 \cdot 10^{-25} \text{ m}^2/\text{s}$$

$$D_{\text{Sn}}^{\text{Cu}_3\text{Sn}} = 2 \cdot 10^{-15} \text{ m}^2/\text{s}$$

$$D_{\text{Sn}}^{\text{Cu}_6\text{Sn}_5} = 2 \cdot 10^{-15} \text{ m}^2/\text{s}$$

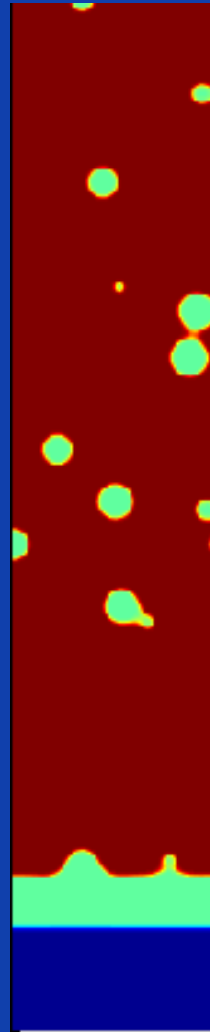
$$D_{\text{Sn}}^{(\text{Sn})} = 2 \cdot 10^{-12} \text{ m}^2/\text{s}$$

$$D_{\text{Sn}}^{\text{surf}} = 2 \cdot 10^{-12} \text{ m}^2/\text{s}$$



Initial compositions

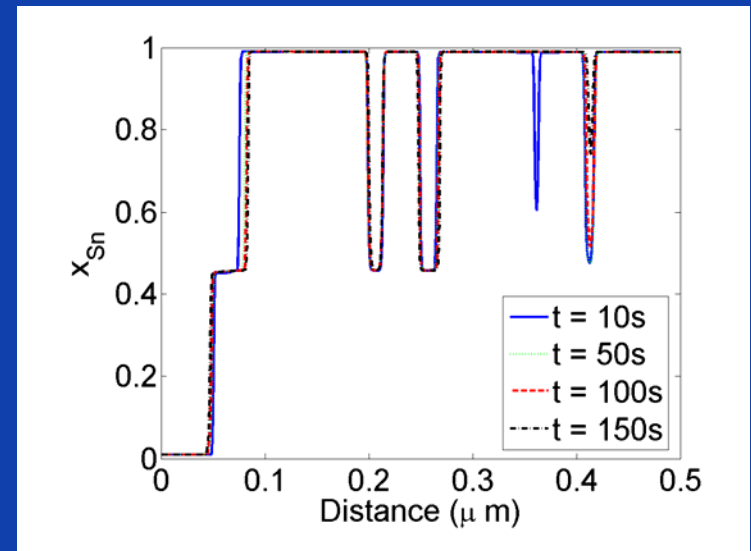
<p>Solder: $x_{Sn,0} = 0.98$</p> <p>(Sn)-matrix $x_{Sn} = 0.999$</p> <p>Cu_6Sn_5-precipitates $x_{Sn} = 0.4545$</p>
<p>IMC layer Cu_6Sn_5 $x_{Sn} = 0.4545$</p>
<p>(Cu)-substrate $x_{Sn} = 0.001$</p>



$$D_{Sn}^{(Cu)} = 10^{-25} \text{ m}^2/\text{s}$$

$$D_{Sn}^{Cu_6Sn_5} = 10^{-16} \text{ m}^2/\text{s}$$

$$D_{Sn}^{(Sn)} = 10^{-12} \text{ m}^2/\text{s}$$



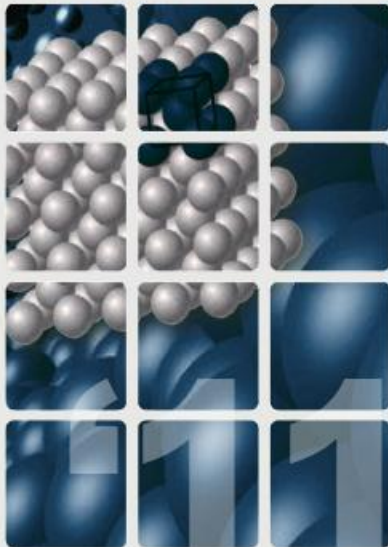
- System size: $0.1 \mu\text{m} \times 0.5 \mu\text{m}$
- Initially $f_V = 0.04$

- For future work: compare with experiments for nanoparticle-reinforced solders for which the grain size is known (J. Janczak, EMPA)

- **The phase-field implementation is able to reproduce thermodynamic and kinetic properties accurately**
- **Important to have realistic free energy functions and atomic diffusion mobilities for microstructure simulations**
 - **But how to treat stoichiometric phases, binary phases ?**
 - **Most general solution: Gibbs free energy over full composition range**
- **Powerful tool for the study of interdiffusion in joint materials**

- **Acknowledgements**
 - **Research Foundation - Flanders (FWO-Vlaanderen)**
 - **Flemish Supercomputing Center (VSC)**
- **More information on *<http://nele.studentenweb.org>***

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PROGRAM

Invited plenary speakers:

Mathematical multiscale techniques

- Serge Prudhomme** (Institute for Computational Engineering and Sciences, The University of Texas at Austin, USA)
Goal-oriented adaptivity for multiscale coupling methods
- Mitchell Luskin** (School of Mathematics, University of Minnesota, USA)
Accurate atomistic-to-continuum coupling methods for solids
- Frederic Legoll** (UR Navier, ENPC, Paris, France)
Finite temperature coarse-graining of atomistic models for solid materials
- Marc Geers** (Mechanical Engineering, Eindhoven University of Technology, the Netherlands)
Homogenization-based multi-scale computational solid mechanics: trends and challenges
- Tim Schulze** (Dept. of Mathematics, University of Tennessee, USA)
Kinetic Monte Carlo simulation of heterostructured nanocrystalline growth
- Aleksandar Donev** (Courant Institute, New York University, USA)
Coarse-grained particle, continuum and hybrid models for complex fluids

Thermodynamic techniques/Alloys

- Chris Wolverton** (Dept. of Materials Science and Engineering, Northwestern University, USA)
TBA
- Xavier Gonze** (Institute of Condensed Matter and Nanoscience, Université Catholique de Louvain, Belgium)
First-principles computation of phonon spectra and thermodynamical properties
- Carolyne Campbell** (NIST/Metallurgy Division, USA)
Development of Multicomponent Diffusion Mobility Databases for Industrial Processing
- Alan Dinsdale (COST MP0602)** (National Physical Laboratory, Teddington, UK)
Computational thermodynamics and CALPHAD modeling for the development of high-temperature lead-free solder alloys
- Ales Kroupa (COST MP0602)** (Institute of Physics of Materials, Academy of Sciences of the Czech Republic)
COST MP0602 lead-free solder database: the design of a consistent thermodynamic database for complex multi-component alloys

Workshop on Multiscale simulation at K.U.Leuven

<http://www.cs.kuleuven.be/conference/multiscale11/>

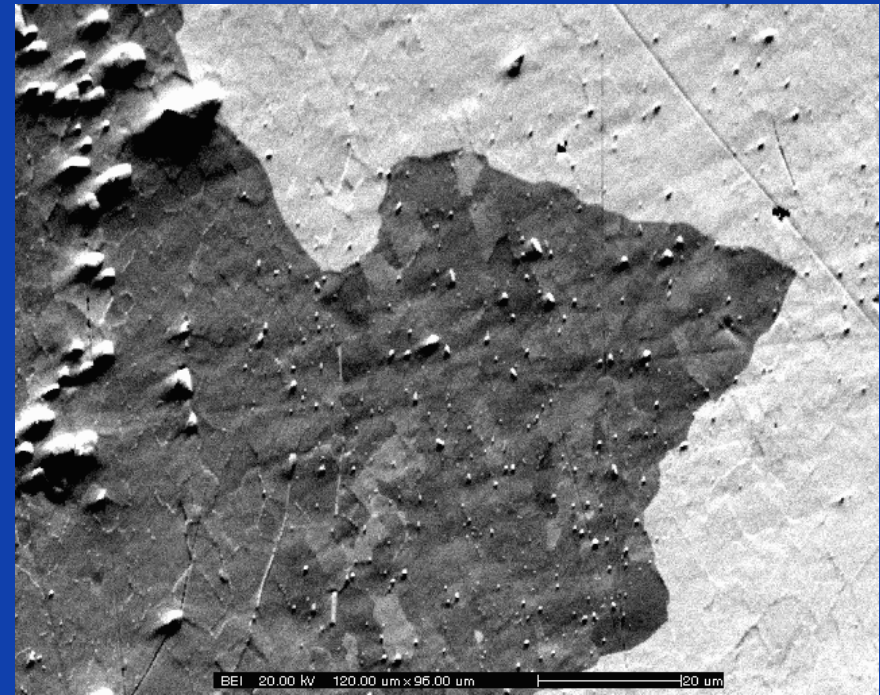
Application examples

- **Coarsening of Al_6Mn precipitates located on a recrystallization front in Al-Mn alloys**

In collaboration with A. Miroux, E. Anselmino, S. van der Zwaag, T. U. Delft

Jerky motion during recrystallization in Al-Mn alloy

- In-situ EBSD observation of recrystallization in AA3103 at 400 °C
 - CamScan X500 Crystal Probe
FEGSEM
- Jerky grain boundary motion
 - Stopping time: 15-25 s
 - Pinning by second-phase precipitates
 - $\text{Al}_6(\text{Fe},\text{Mn})$, $\alpha\text{-Al}_{12}(\text{Fe},\text{Mn})_3\text{Si}$
- Added to phase field model
 - Grain boundary diffusion
 - Driving force for recrystallization

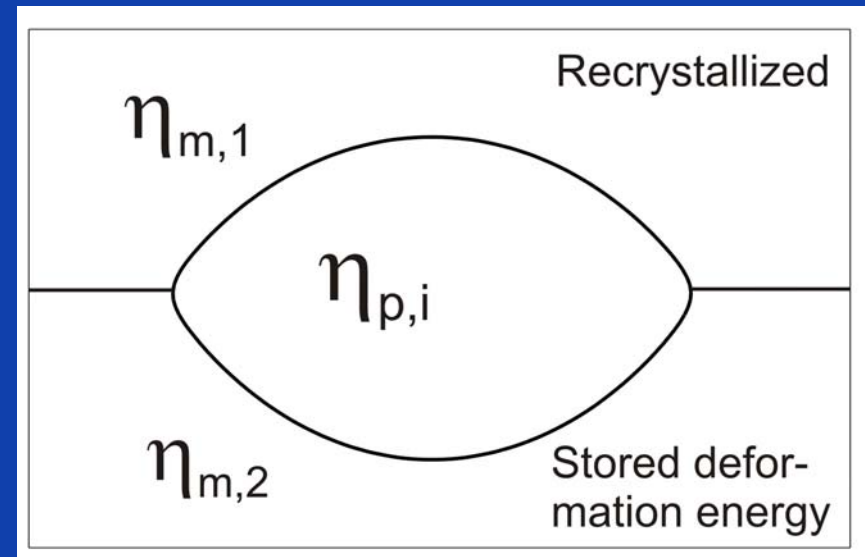


20 μm

- **Multiple order parameter representation:** $\eta_{m,1}(\vec{r}, t), \eta_{m,2}(\vec{r}, t), \dots, \eta_{p,i}(\vec{r}, t), \dots$

$$(\eta_{m,1}, \eta_{m,2}, \dots, \eta_{p,i}, \dots) = (1, 0, \dots, 0, \dots), (0, 1, \dots, 0, \dots), \dots (0, 0, \dots, 1, \dots), \dots$$

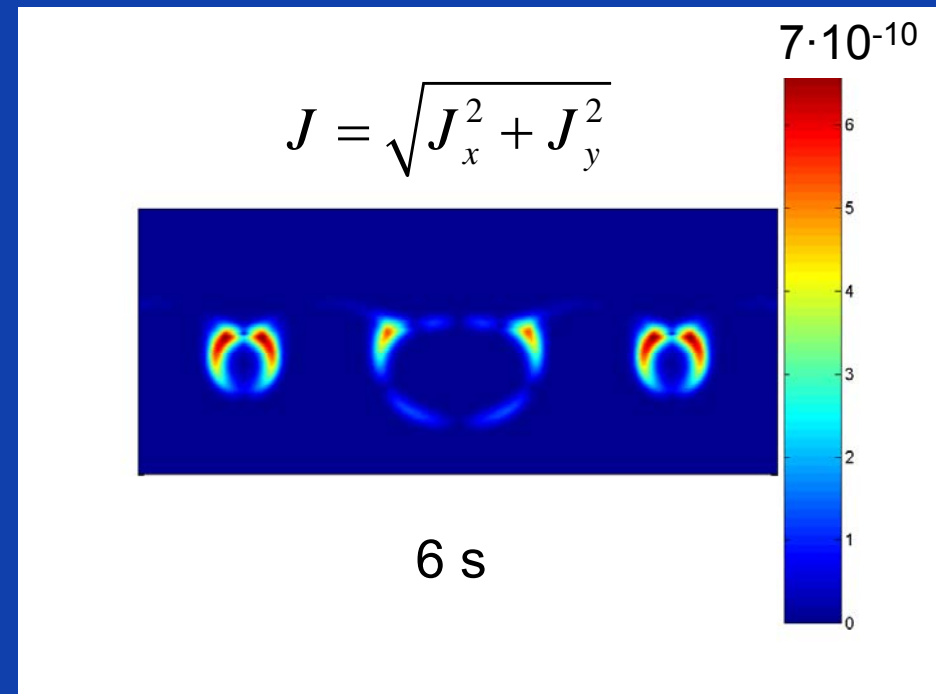
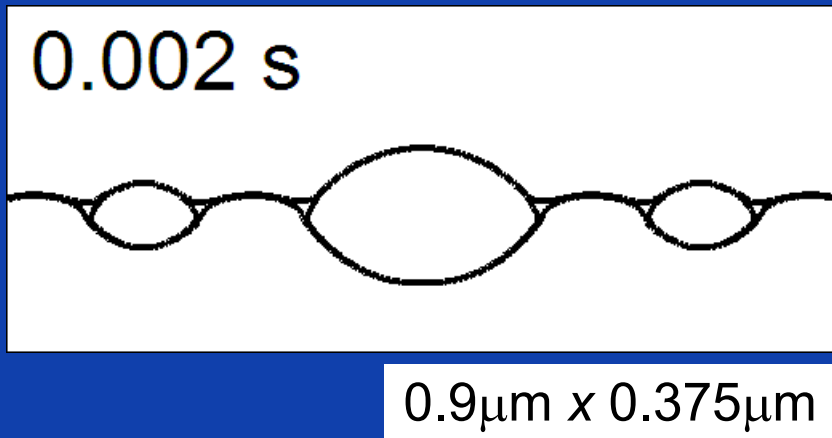
- **Mn composition field:** $x_{Mn}(\vec{r}, t)$
- **Homogeneous driving pressure for recrystallization:** m_d
- **Bulk diffusion + Surface diffusion**



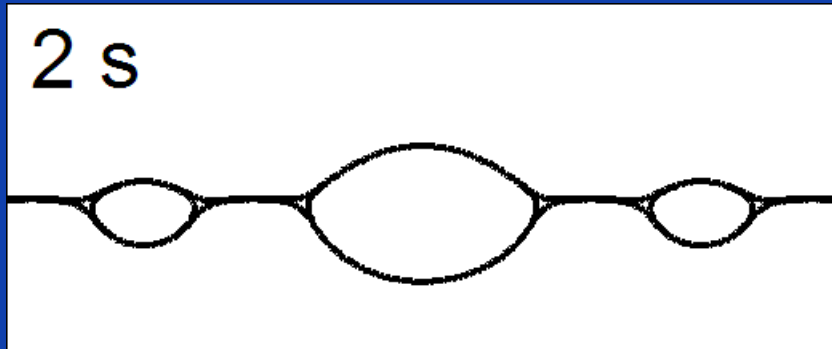
Grain boundary energy high angle	$\gamma_h = 0.324 \text{ J/m}^2$
Interfacial energy Al_6Mn precipitates	$\gamma_{pr} = 0.3 \text{ J/m}^2$
Mobility high angle grain boundary At solute content 0.3w% Mn	$M_h = 2.94 \cdot 10^{-11} \text{ m}^2\text{s/kg}$ (Miroux et al., Mater. Sci. Forum, 467-470, 393(2004))
Equilibrium composition of matrix	$c_{\text{Mn,eq}} = 0.0524 \text{ w\% (0.02456 at\%)}$ (PhD thesis Lok 2005)
Actual composition of matrix (supersaturated)	$c_{\text{Mn}} = 0.3 \text{ w\% (0.1474 at\%)}$ (PhD thesis Lok 2005)
Mn diffusion in fcc Al	$D_{0,\text{bulk}} = 10^{-2} \text{ m}^2\text{/s}, Q_{\text{bulk}} = 211 \text{ kJ/mol}$ $\rightarrow D_{\text{bulk}} = 5.5973 \cdot 10^{-18} \text{ m}^2\text{/s}$
Pipe diffusion high angle boundaries, precipitate/matrix interface	$D_{0,p} = D_{0,\text{bulk}}, Q_p = 0.65Q_{\text{bulk}}$ $\rightarrow D_p = 1.2195 \cdot 10^{-12} \text{ m}^2\text{/s}$
Bulk energy density: $f^p = A^p(x-x^p_0)^2$	$A^m = 6 \cdot 10^{11}; x^m_0 = 0.000258$ $A^p = 6 \cdot 10^{12}; x^p_0 = 0.1429$

- $P_D < P_{ZS}$ ($P_D \approx P_{ZS}$)
 - Pinning: $P_{ZS}=3.6$ MPa
 - Rex: $P_D=3.1$ MPa

- Unpinning mainly through surface diffusion around precipitates

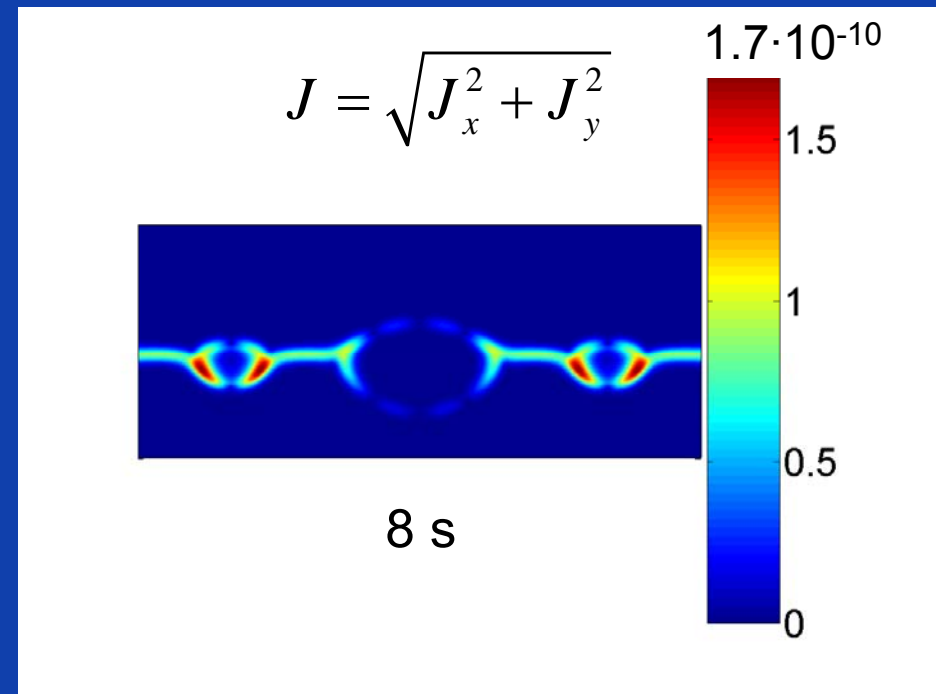


- $P_D \lll P_{Zs}$
 - Pinning: $P_{Zs} = 3.6 \text{ MPa}$
 - Rex: $P_D = 1.1 \text{ MPa}$



0.9 μm x 0.375 μm

- Unpinning through grain boundary diffusion



- **Multi-phase-field model**

- **Phase fields** $\phi_1, \phi_2, \phi_3, \dots, \phi_p, \quad \sum_{i=1}^p \phi_i = 1$

- **Free energy** $f_{\text{int}} = \sum_{i \neq j} \frac{4\sigma_{i,j}}{\eta_{i,j}} \left\{ \frac{\eta_{i,j}^2}{\pi^2} |\nabla \phi_i \cdot \nabla \phi_j| + \phi_i \phi_j \right\}$
 $0 < \phi_{i,j} < 1$

- Double obstacle, higher order terms, gradient term non-variational
- Interpolation: zero-slope or thermodynamic consistency

Steinbach et al.

MICRESS phase-field code

H. Garcke, B. Nestler, B. Stoth, SIAM J. Appl. Math. 60 (1999) p 295.

L.-Q. Chen and W. Yang, PRB, 50 (1994) p15752

A. Kazaryan et al., PRB, 61 (2000) p14275

- **Multi-order parameter models**

- **Order parameters** $\eta_1, \eta_2, \dots, \eta_i(\vec{r}, t), \dots, \eta_p, \quad \left(\sum_{i=1}^p \eta_i \neq 1 \right)$

- **Interfacial energy** $f_{\text{int}} = m \left(\sum_{i=1}^p \left(\frac{\eta_i^4}{4} - \frac{\eta_i^2}{2} \right) + \sum_{i=1}^p \sum_{j<i}^p \gamma_{i,j} \eta_i^2 \eta_j^2 + \frac{1}{4} \right) + \frac{\kappa(\eta)}{2} \sum_{i=1}^p (\vec{\nabla} \eta_i)^2$

- **Vector valued model**

- Orientation field (θ) and phase field (ϕ)

*R. Kobayashi, J.A. Warren,
W.C. Carter, Physica D, 119
(1998) p415*

- Free energy $f_{\text{int}} = f(\phi, |\nabla\phi|, |\nabla\theta|)$

- **2-phase solidification**

- Phase fields

$$\varphi_1, \varphi_2, \varphi_3, \quad \sum_{i=1}^3 \varphi_i = 1$$

*R. Folch and M. Plapp, PRE, 72
(2005) n° 011602*

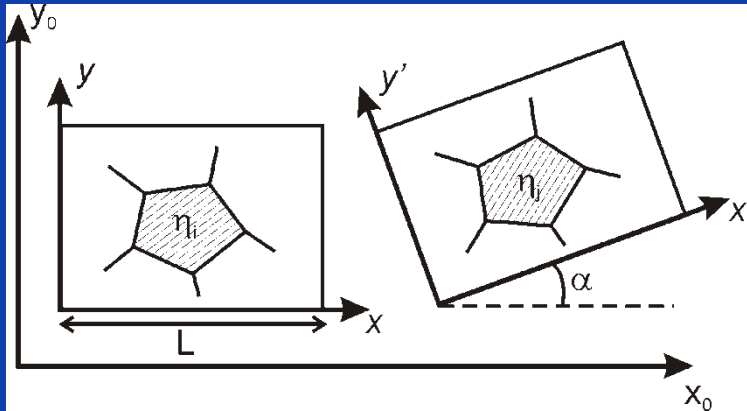
- Fifth order interpolation functions $g_i(\phi_1, \phi_2, \phi_3)$
 - Zero-slope and thermodynamic consistent
 - Order g_i increases with number of phase-fields

- **Multi-order parameter + 4th order gradient terms**

*I.M. McKenna, M.P. Gururajan,
P.W. Voorhees, J. Mater. Sci., 44
(2009) p2206*

- **Phase field crystal and amplitude equations**

- Mathematically, the model equations are invariant to rotation, but ...
- the order parameters represent orientations in a fixed reference frame.



grid spacing Δh

physical width of domain L

rotational symmetry n

- The precision of α depends on the numerical setup,

$$\Delta\alpha \approx \frac{1}{\cos\alpha} \frac{\Delta h}{L}$$

- For the model to be rotational invariant in practice, lower limit of amount of order parameters p :

$$p > \frac{\sqrt{2}\pi L}{n\Delta h}$$

J. Heulens and N. Moelans, Scripta Mat. (2010)